

# **Electronic structure of solids : temperature dependence and zero-point motion effect**

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Collaborators :

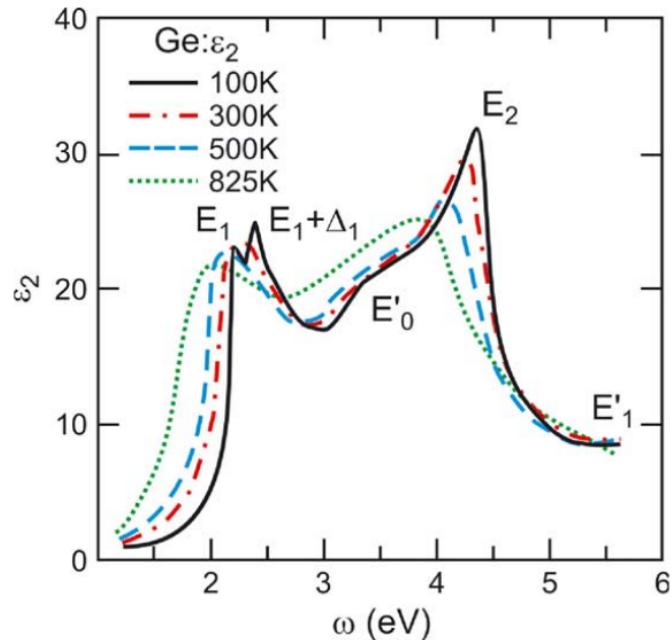
S. Poncé, Y. Gillet, J. Laflamme, U.C. Louvain, Belgium

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A. Marini, CNR Italy

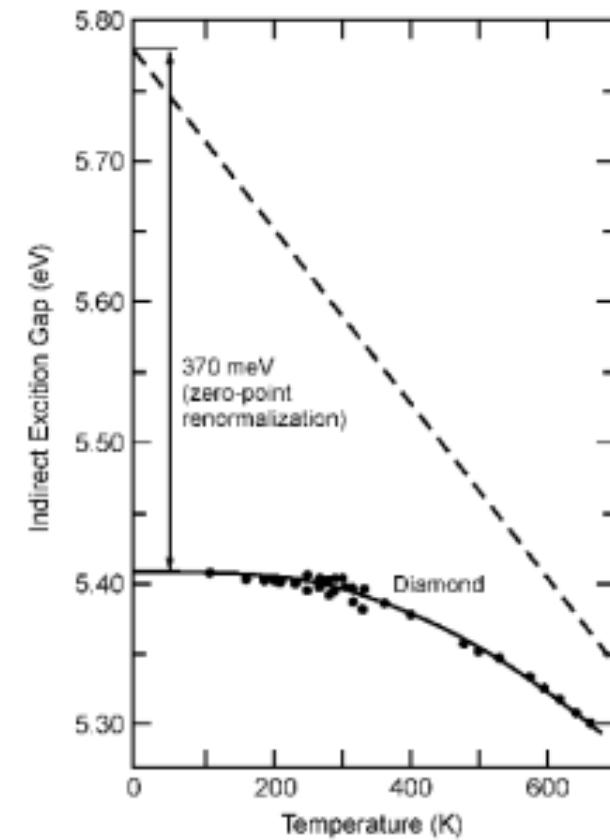
P. Boulanger, CEA Grenoble

# Temperature dependence of electronic/optical properties



L. Viña, S. Logothetidis and M. Cardona,  
*Phys. Rev. B* **30**, 1979 (1984)

- peaks **shift** in energy
- peaks **broaden** with increasing temperature : decreased electron lifetime

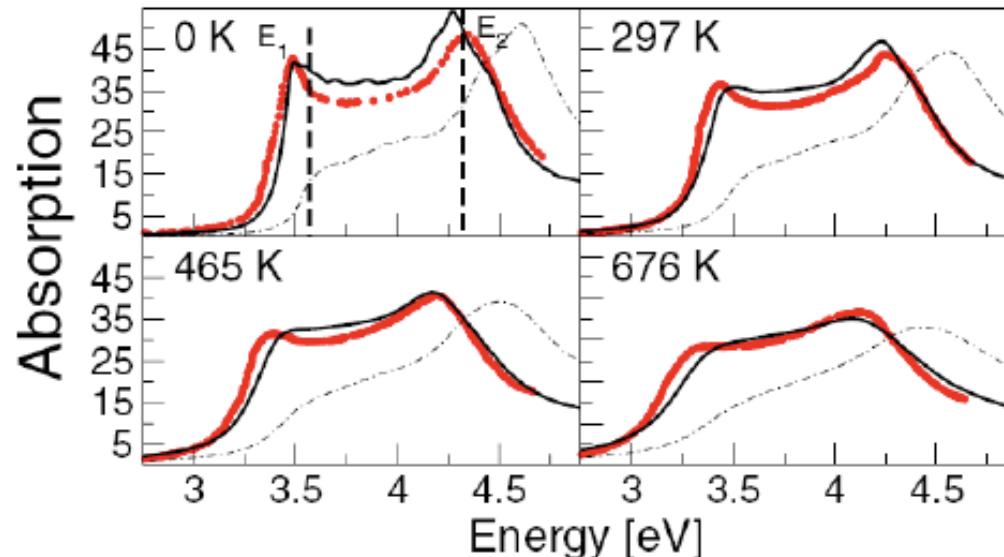


- even at 0K, vibrational effects are important, due to Zero-Point Motion

Usually, not taken into account in First-principles calculations !

M. Cardona, *Solid State Comm.* **133**, 3 (2005)

# Allen-Heine-Cardona theory + first-principles

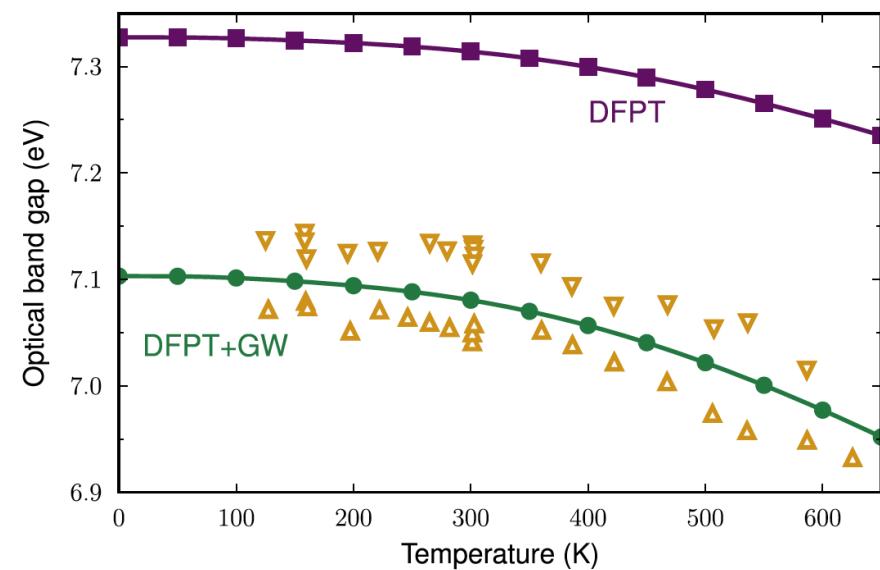


A. Marini, *Physical Review Letters* 101, 106405 (2008)

Diamond Zero-point motion  
in DFT : 0.4 eV for the direct gap

Diamond Zero-point motion  
in DFT+GW : 0.63 eV for the direct gap,  
in agreement with experiments

Optical absorption of Silicon.  
Excellent agreement with Exp.  
Mostly broadening effect,  
imaginary part of the Fan term  
(not discussed in this talk)



# Overview

1. Motivation
2. Thermal expansion and phonon population effects
3. Ab initio Allen-Heine-Cardona (AHC) theory
4. Temperature effects with GW electronic structure
5. Breakdown of the adiabatic AHC theory  
for infra-red active materials
6. Many-body perturbation theory with vibrational effects

References :

- (1) X. Gonze, P. Boulanger and M. Côté, *Ann. Phys* 523, 168 (2011)
- (2) S. Poncé *et al*, *Comput. Materials Science* 83, 341 (2014)
- (3) G. Antonius, S. Poncé, P. Boulanger, M. Côté and X. Gonze, *Phys. Rev. Lett.* 112, 215501 (2014)
- (4) S. Poncé *et al*, *Phys. Rev. B* 90, 214304 (2014)
- (5) A. Marini, S. Poncé and X. Gonze, *Phys. Rev. B* 91, 224310 (2015)
- (6) S. Poncé *et al*, *J. Phys. Chem* 143, 102813 (2015)
- (7) G. Antonius *et al*, *Phys. Rev. B* 92, 085137 (2015)
- (8) XG et al , *Comput. Phys. Comm.* 205, 106 (2016)

Note : For the assessment of the size rigid-ion effects, not mentioned in this talk, see (1) and (4)

# Thermal expansion and phonon population effects

# Divide and conquer ...

Constant-pressure temperature dependence of the electronic eigenenergies : **two contributions**

$$\left( \frac{\partial \varepsilon_{n\vec{k}}}{\partial T} \right)_P = \left( \frac{\partial \varepsilon_{n\vec{k}}}{\partial T} \right)_V + \left( \frac{\partial \varepsilon_{n\vec{k}}}{\partial \ln V} \right)_T \left( \frac{\partial \ln V}{\partial T} \right)_P$$

Constant volume      Constant temperature

$= \alpha_P(T)$   
Thermal expansion coefficient

Contribution of the **phonon population**, i.e. the vibrations of the atomic nuclei, **at constant volume**

+

Contribution of the **thermal expansion**, i.e. the change in volume of the sample, **at constant temperature**

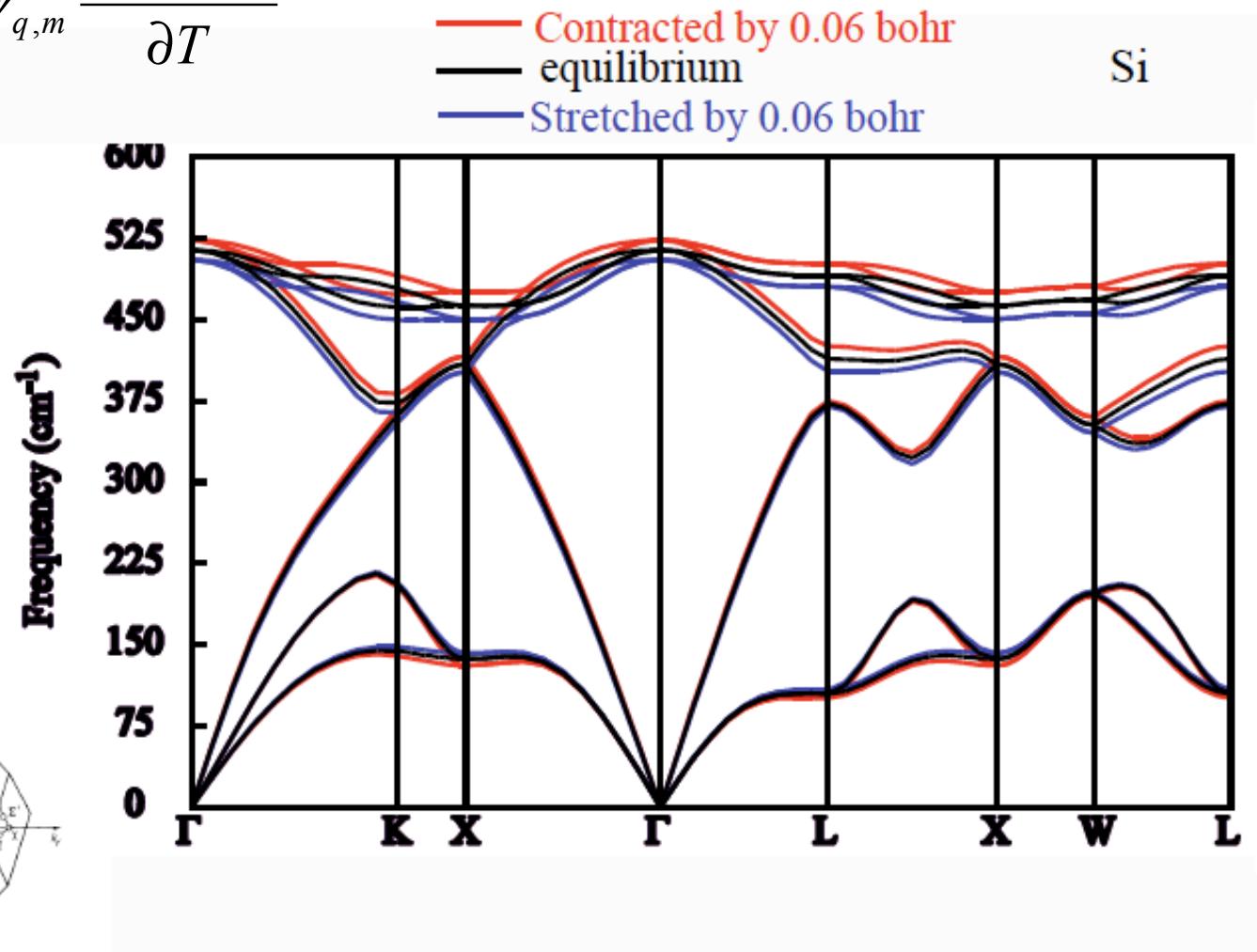
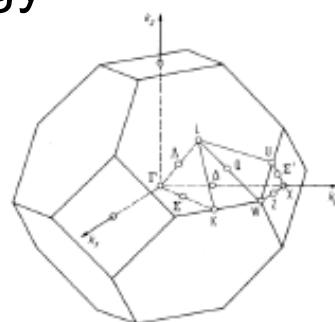
# Ab initio thermal expansion

$$\alpha(T) = \frac{V}{3B} \sum_{q,m} \frac{1}{\omega_{q,m}} \gamma_{q,m} \frac{\partial n(\omega_{q,m})}{\partial T}$$

Mode-Grüneisen parameters

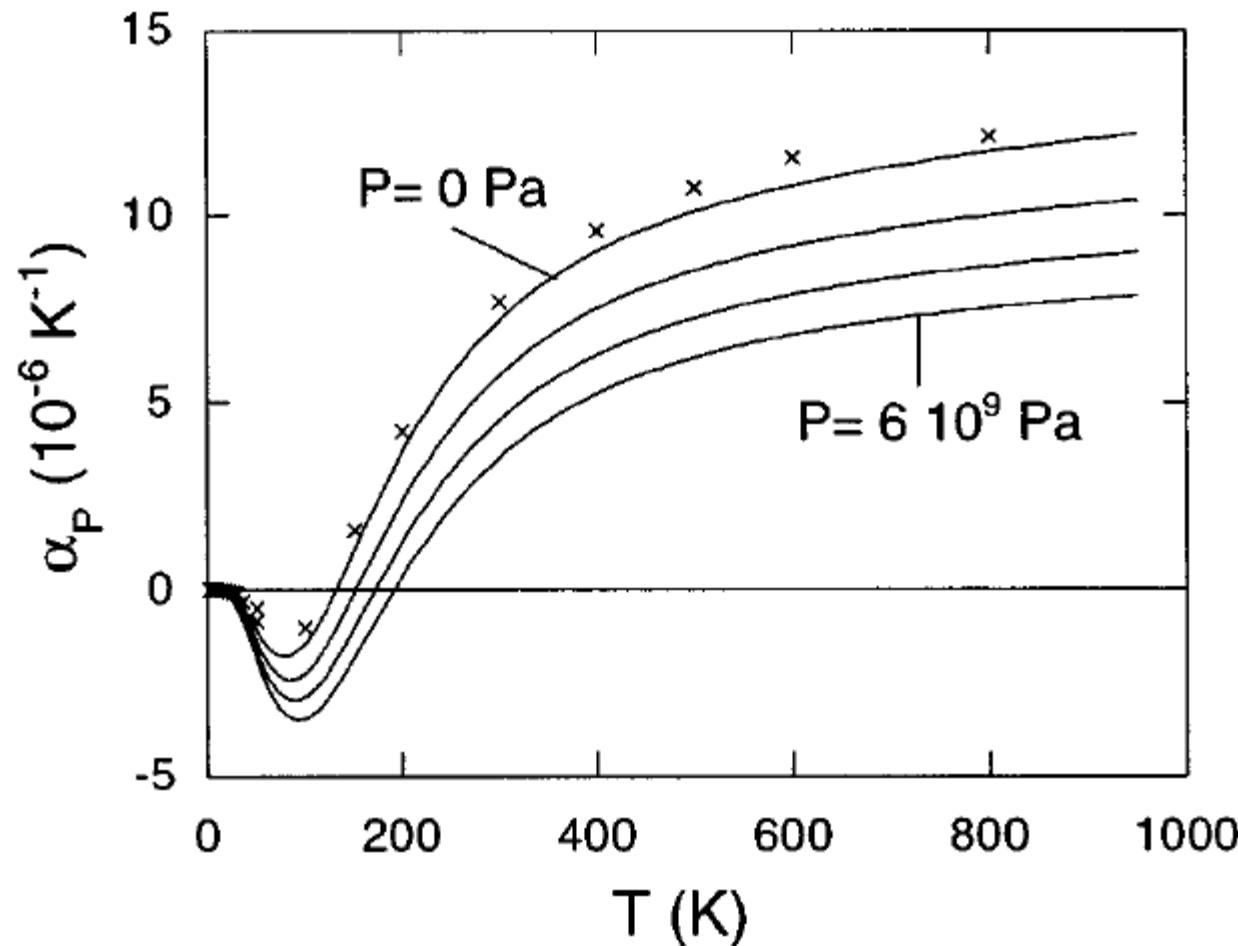
$$\gamma_{m,q} = -\frac{\partial(\ln \omega_{m,q})}{\partial(\ln V)}$$

Alternative path : minimisation of free energy



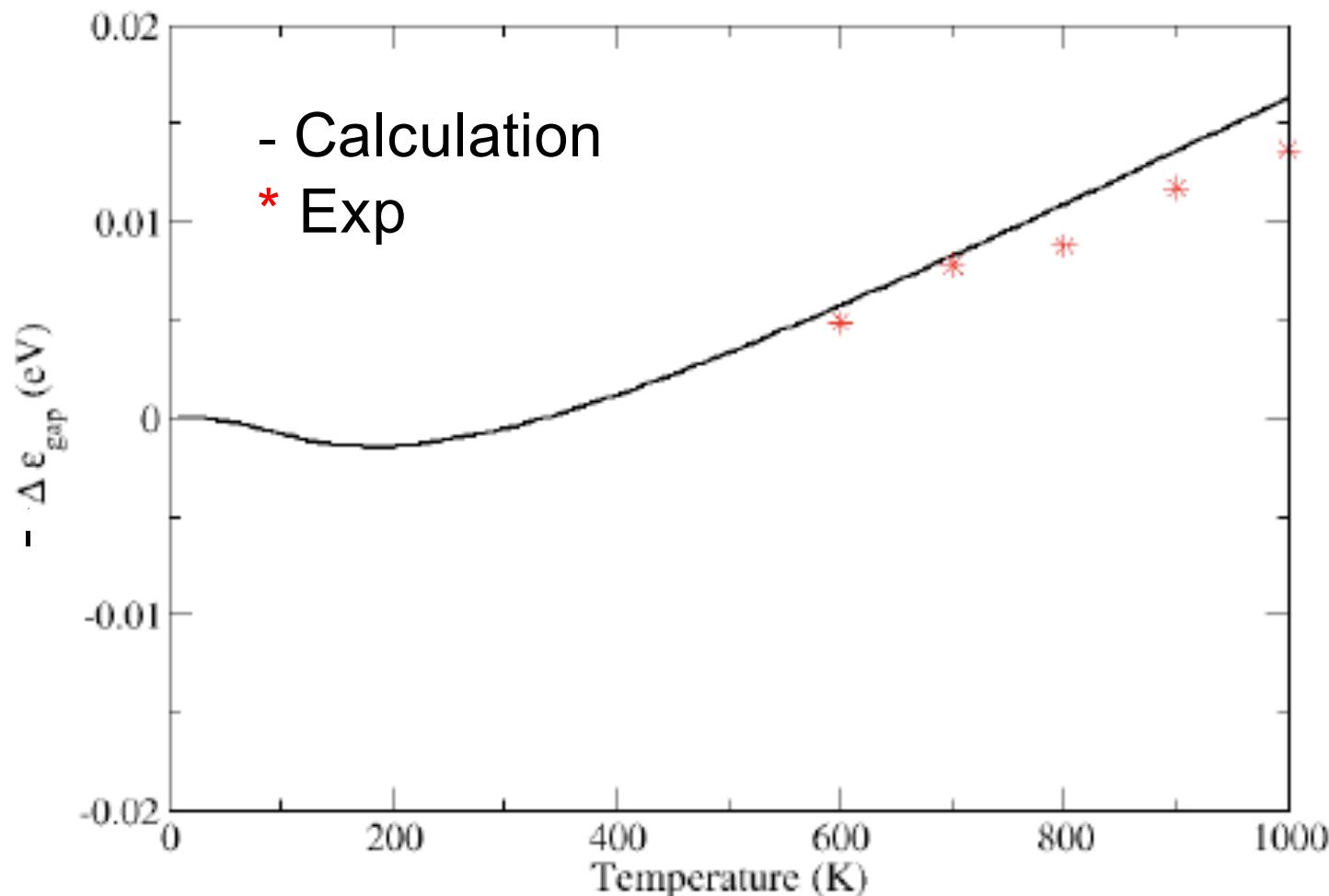
# Ab initio thermal expansion

Linear thermal expansion coefficient of bulk silicon



G.-M. Rignanese, J.-P. Michenaud and XG Phys. Rev. B 53, 4488 (1996)

# Thermal expansion contribution to the gap of Si



But **total exper. change between 0K and 300K = 0.06 eV !**  
...Thermal expansion contribution is negligible (for Si) ...

# Phonon population effects

Different levels of approximation :

- dynamics of the nuclei ... **classical** ... quantum ?
- harmonic** treatment of vibrations or **anharmonicities** ?
- adiabatic decoupling of nuclei and electronic dynamic, or non-adiabatic corrections ?
- independent electronic quasi-particles** (DFT or GW), or many-body approach with **spectral functions** ?

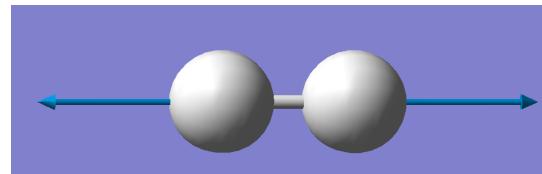
... At least 5 first-principle methodologies :

- (1) Time-average
- (2) Thermal average
- (3) Harmonic approximation + thermal average
- (4) Diagrammatic approach (Allen-Heine-Cardona)
- (5) Exact factorization (H. Gross and co-workers)

# Nuclear dynamics : dimers

Diatomc molecules = simplest system to study temperature dependence of eigenvalues.

- discrete levels, well described with the theory of the molecular orbitals
- only one relevant vibration mode.



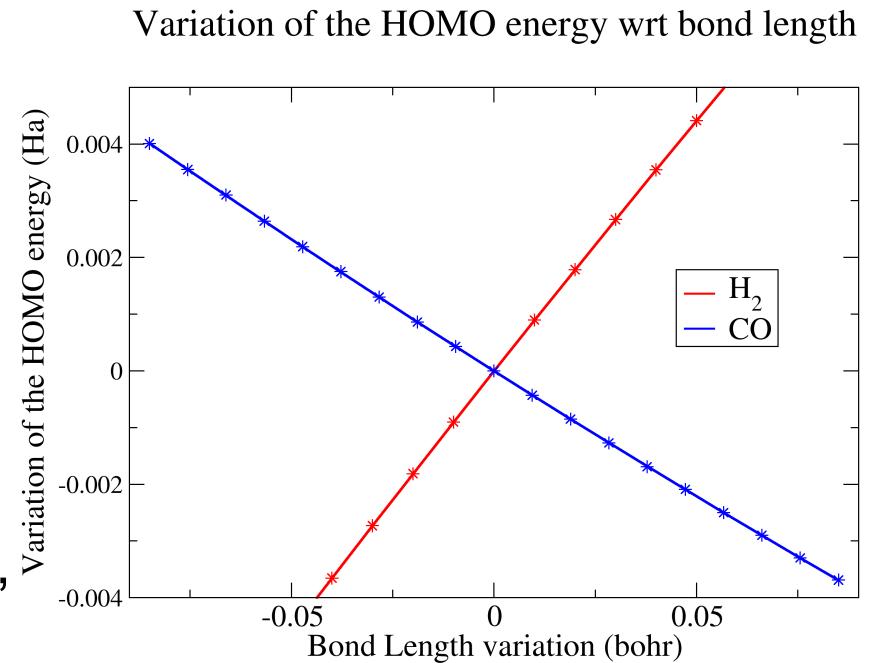
(6 modes decouple as 3 translations, 2 rotations + the stretch.)

# Average eigenenergies in the BO approx.

Electronic eigenenergies,  
function of the bond length  $\varepsilon_n(\Delta R) \Rightarrow$

- (1) Time-average of eigenenergies  
from Molecular Dynamics trajectories,  
 $\Delta R(t)$  at average T, with

$$\varepsilon_n(T) = \lim_{\tau \rightarrow \infty} \frac{1}{\tau} \int_0^\tau \varepsilon_n(\Delta R(t)) dt$$



Pros : well-defined procedure ; compatible with current implementations  
and computing capabilities ;  $\varepsilon_n(\Delta R(t))$  from DFT or GW ;  
anharmonicities

Cons : if classical dynamics => no zero-point motion ; adiabatic  
(vibrations, but no exchange of energy !) ; hard for solids (supercell)

# Average eigenenergies in the BO approx.

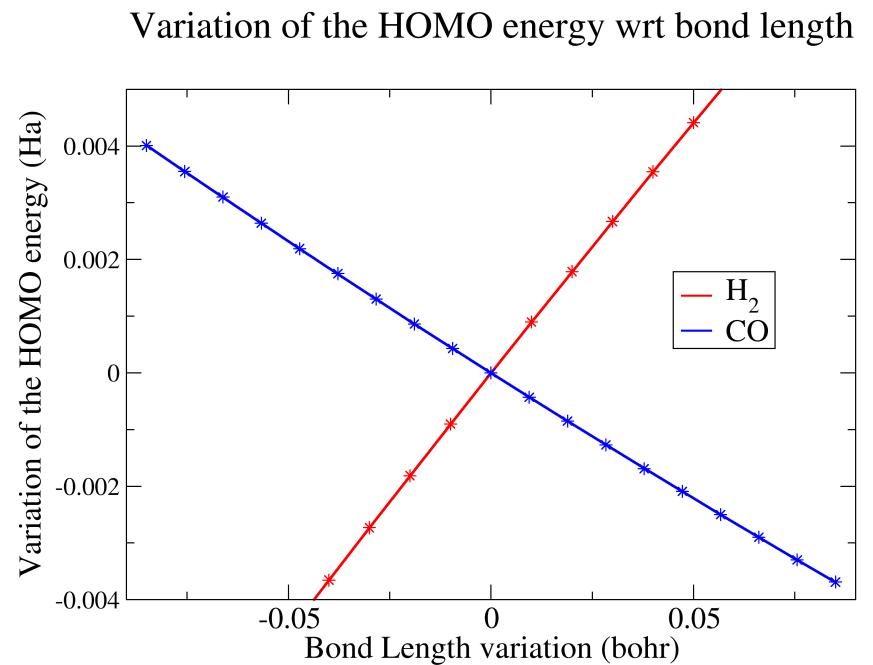
Electronic eigenenergies  
function of the bond length  $\varepsilon_n(\Delta R)$

(2) Thermal average with accurate  
quantum vibrational states,

$$\varepsilon_n(T) = \frac{1}{Z} \sum_m e^{-\frac{E_{ph}(m)}{k_B T}} \left( \int \chi_m^*(\Delta R) \varepsilon_n(\Delta R) \chi_m(\Delta R) d\Delta R \right) \quad Z = \sum_m e^{-\frac{E_{ph}(m)}{k_B T}}$$

Pros : zero-point motion ;  $\varepsilon_n(\Delta R(t))$  from DFT or GW ;  
anharmonicities

Cons : hard to sample more than a few vibrational degrees of freedom ;  
adiabatic (vibrations, but no exchange of energy !)



# Average eigenenergies : BO and harmonic approx.

(3) Thermal average with quantum vibrational states in the **harmonic approximation**, **and** expansion of  $\varepsilon_n(\Delta R)$  to second order

$$E_{ph}(m) = \hbar\omega(m + \frac{1}{2})$$

$$n_{vib}(T) = \frac{1}{e^{\frac{-\hbar\omega}{k_B T}} - 1}$$

T-dependent phonon occupation number (Bose-Einstein)

$$\varepsilon_n = \varepsilon_n^0 + \cancel{\frac{\partial \varepsilon_n}{\partial R} \Delta R} + \frac{1}{2} \boxed{\frac{\partial^2 \varepsilon_n}{\partial R^2}} \Delta R^2$$

$$\delta\varepsilon_n(T) = \boxed{\frac{\partial \varepsilon_n}{\partial n_{vib}} \left( n_{vib}(T) + \frac{1}{2} \right)}$$

Pros : zero-point motion ;  $\varepsilon_n(\Delta R)$  from DFT or GW ;  
tractable ... for molecules ...

Cons : hard for solids (supercells) ; no anharmonicities ;  
adiabatic (vibrations, but no exchange of energy !)

# Ab initio Allen-Heine-Cardona theory

# Long history of the theory of T-dependent effects

In a **semi-empirical** context (empirical pseudopotential, tight-binding) ...

Work from the '50 :

H. Y. Fan. Phys. Rev. **78**, 808 (1950) ; **82**, 900 (1951)

E. Antoncik. Czechosl. Journ. Phys. **5**, 449 (1955). Debye-Waller contribution.

H. Brooks. Adv. Electron **7**, 85 (1955) + Yu (PhD thesis, unpubl., Brooks supervisor)



Within 2nd order perturbation theory treatment  
of electron-phonon effect, **both** contributions are needed (of course !).

Unification by :

Allen + Heine, J. Phys. C **9**, 2305 (1976).

Allen + Cardona, Phys. Rev. B **24**, 7479 (1981) ; **27**, 4760 (1983).

=> the Allen-Heine-Cardona (AHC) theory

# Allen-Heine-Cardona (AHC) formalism

Second-order (time-dependent) perturbation theory  
(no average contribution from first order)

For solids (phonons have crystalline momentum)

If adiabatic BO ... neglect the phonon frequencies with respect to the electronic gap, no transfer of energy :

$$\delta\epsilon_{\vec{k}n}(T, V = \text{const}) = \frac{1}{N_{\vec{q}}} \sum_{\vec{q}j} \frac{\partial \epsilon_{\vec{k}n}}{\partial n_{\vec{q}j}} \left( \langle \hat{n}_{\vec{q}j} \rangle(T) + \frac{1}{2} \right) \quad + \text{occupation number from Bose-Einstein statistics}$$

$$\frac{\partial \epsilon_{\vec{k}n}}{\partial n_{\vec{q}j}} = \frac{1}{2\omega_{\vec{q}j}} \sum_{\kappa a \kappa' b} \frac{\partial^2 \epsilon_{\vec{k}n}}{\partial R_{\kappa a} \partial R_{\kappa' b}} \frac{\xi_{\kappa a}(\vec{q}j) \xi_{\kappa' b}(-\vec{q}j)}{\sqrt{M_\kappa M_{\kappa'}}} e^{iq.(R_{\kappa' b} - R_{\kappa a})}$$

Electron-phonon coupling energy (EPCE)

“Phonon mode factor”

$\xi_{\kappa a}(\vec{q}j)$  phonon eigenmodes,  $\kappa$  = atom label, a=x, y, or z

# Eigenvalue changes

$$\left( \frac{\partial^2 \varepsilon_{\vec{k}n}}{\partial R_{\kappa a} \partial R_{\kappa' b}} \right) ?$$

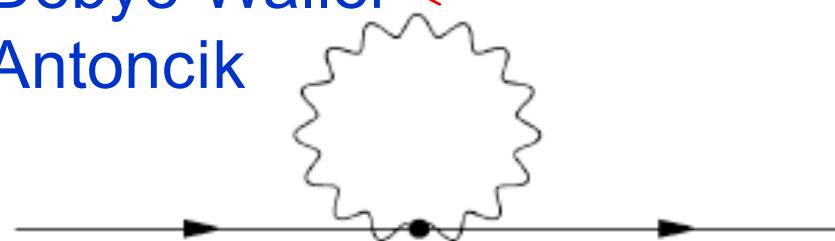
$$\varepsilon_{\vec{k}n} = \langle \phi_{\vec{k}n} | \hat{H}_{\vec{k}} | \phi_{\vec{k}n} \rangle \quad \hat{H} = \hat{T} + \hat{V}_{\text{nucl}} + \int \frac{\rho(r')}{|r-r'|} dr' + \frac{dE_{xc}}{d\rho(r)}$$

Hellman-Feynman theorem :  $\varepsilon_{\vec{k}n}^{(1)} = \langle \phi_{\vec{k}n}^{(0)} | \hat{H}_{\vec{k}}^{(1)} | \phi_{\vec{k}n}^{(0)} \rangle$

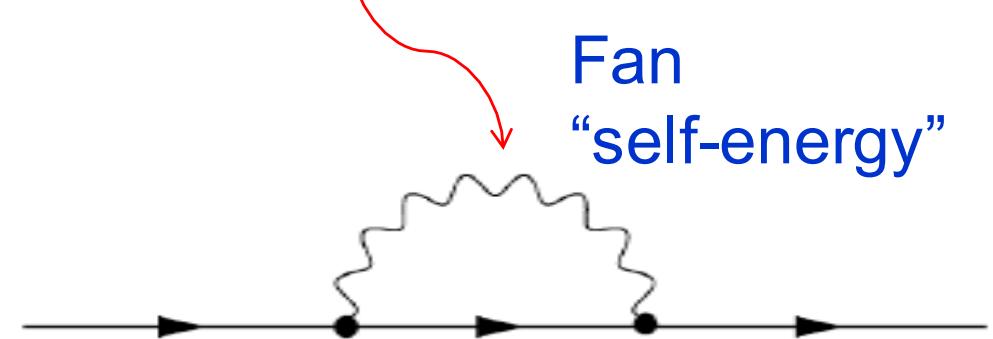
One more derivative :

$$\varepsilon_{\vec{k}n}^{(2)} = \boxed{\langle \phi_{\vec{k}n}^{(0)} | \hat{H}_{\vec{k}}^{(2)} | \phi_{\vec{k}n}^{(0)} \rangle} + \boxed{\frac{1}{2} \left( \langle \phi_{\vec{k}n}^{(0)} | \hat{H}_{\vec{k}+\vec{q}}^{(1)} | \phi_{\vec{k}+\vec{q}n}^{(1)} \rangle + (\text{c.c}) \right)}$$

Debye-Waller  
Antoncik



Fan  
“self-energy”



In AHC,  $|\phi_n^{(1)}\rangle$  obtained by sum-over-states  $|\phi_n^{(1)}\rangle = \sum_{m \neq n} |\phi_m^{(0)}\rangle \frac{\langle \phi_m^{(0)} | \hat{H}^{(1)} | \phi_n^{(0)} \rangle}{\varepsilon_n - \varepsilon_m}$

# Derivatives of the Hamiltonian ?

$$\hat{H} = \hat{T} + \hat{V}_{nucl} + \int \frac{\rho(r')}{|r-r'|} dr' + \frac{dE_{xc}}{d\rho(r)}$$
$$\hat{V}_{nucl} = \sum_{\kappa} V_{\kappa}(r - R_{\kappa})$$

In AHC, use of semi-empirical pseudopotential => rigid-ion approximation

Upon infinitesimal displacements of the nuclei,  
the rearrangement of electrons due to the perturbation is ignored

$$\Rightarrow \hat{H}^{(2)} \text{ pure site-diagonal !} \quad \frac{\partial^2 \hat{V}_{nucl}}{\partial R_{\kappa a} \partial R_{\kappa' b}} = 0 \text{ for } \kappa \neq \kappa'$$

$\Rightarrow$  Debye-Waller contribution pure site-diagonal !

Moreover, invariance under pure translations

$$0 = \epsilon_n^{(2)} = \langle \phi_n^{(0)} | \hat{H}_{transl}^{(2)} | \phi_n^{(0)} \rangle + \frac{1}{2} \left( \langle \phi_n^{(0)} | \hat{H}_{transl}^{(1)} | \phi_n^{(1)} \rangle + (c.c) \right)$$

$\Rightarrow$  Reformulation of the Debye-Waller term.

# Ad. AHC = Ad. Fan + rigid-ion Debye-Waller

$$\frac{\partial \epsilon_{\vec{k}n}}{\partial n_{\vec{q}j}} = \left( \frac{\partial \epsilon_{\vec{k}n}(\text{Fan})}{\partial n_{\vec{q}j}} \right) + \left( \frac{\partial \epsilon_{\vec{k}n}(DW^{RIA})}{\partial n_{\vec{q}j}} \right)$$

$$\frac{\partial \epsilon_{\vec{k}n}(\text{Fan})}{\partial n_{\vec{q}j}} = \frac{1}{\omega_{\vec{q}j}} \Re \sum_{\kappa a \kappa' b n'} \frac{\langle \phi_{\vec{k}n} | \nabla_{\kappa a} H_{\kappa} | \phi_{\vec{k}+\vec{q}n'} \rangle \langle \phi_{\vec{k}+\vec{q}n'} | \nabla_{\kappa' b} H_{\kappa'} | \phi_{\vec{k}n} \rangle}{\epsilon_{\vec{k}n} - \epsilon_{\vec{k}+\vec{q}n'}} \frac{\xi_{\kappa a}(\vec{q}j) \xi_{\kappa' b}(-\vec{q}j)}{\sqrt{M_{\kappa} M_{\kappa'}}} e^{iq.(R_{\kappa' b} - R_{\kappa a})}$$

$$\frac{\partial \epsilon_{\vec{k}n}(DW^{RIA})}{\partial n_{\vec{q}j}} = -\frac{1}{\omega_{\vec{q}j}} \Re \sum_{\kappa a \kappa' b n'} \frac{\langle \phi_{\vec{k}n} | \nabla_{\kappa a} H_{\kappa} | \phi_{\vec{k}n'} \rangle \langle \phi_{\vec{k}n'} | \nabla_{\kappa' b} H_{\kappa'} | \phi_{\vec{k}n} \rangle}{\epsilon_{\vec{k}n} - \epsilon_{\vec{k}n'}} \times \frac{1}{2} \left( \frac{\xi_{\kappa a}(\vec{q}j) \xi_{\kappa b}(-\vec{q}j)}{M_{\kappa}} + \frac{\xi_{\kappa' a}(\vec{q}j) \xi_{\kappa' b}(-\vec{q}j)}{M_{\kappa'}} \right)$$

**Good** : only **first-order** electron-phonon matrix elements are needed (+ standard ingredients from first-principles phonon/band structure calculations) ; no supercell calculations

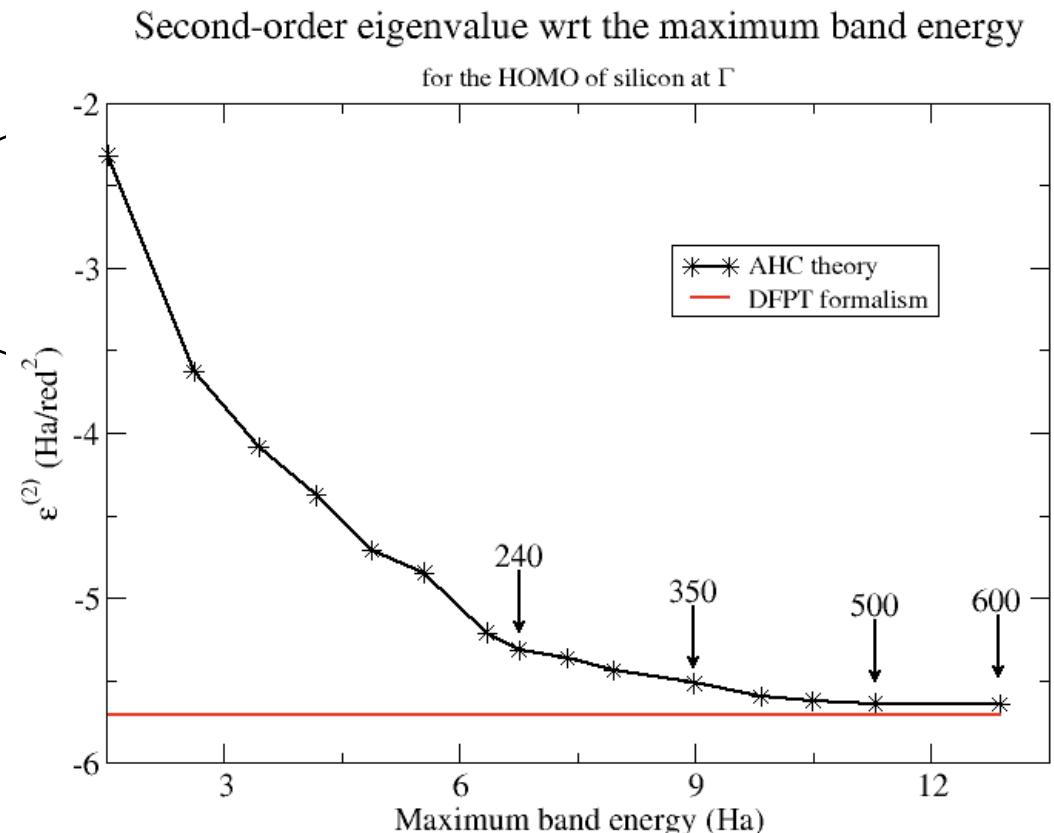
**Bad** : (1) summation over a large number of unoccupied states n'  
 (2) is the **rigid-ion approx.** valid for first-principles calculations ?  
 (3) If first-principles calculations : **DFT** electron-phonon matrix elements, as well as eigenenergies, while MBPT should be used  
 (4) Adiabatic approx. : **phonon frequencies neglected in denominator**

# Implementation

Sum over state present in the AHC formalism, replaced by the use of Density-Functional Perturbation Theory quantities  
=> large gain in speed.

$$\left| \phi_n^{(1)} \right\rangle = \sum_{m \neq n} \left| \phi_m^{(0)} \right\rangle \frac{\langle \phi_m^{(0)} | \hat{H}^{(1)} | \phi_n^{(0)} \rangle}{\epsilon_n - \epsilon_m}$$

For converged calculations  
for silicon :  
sum over states 125 h  
DFPT 17h



# Numerical study : ZPR in diamond

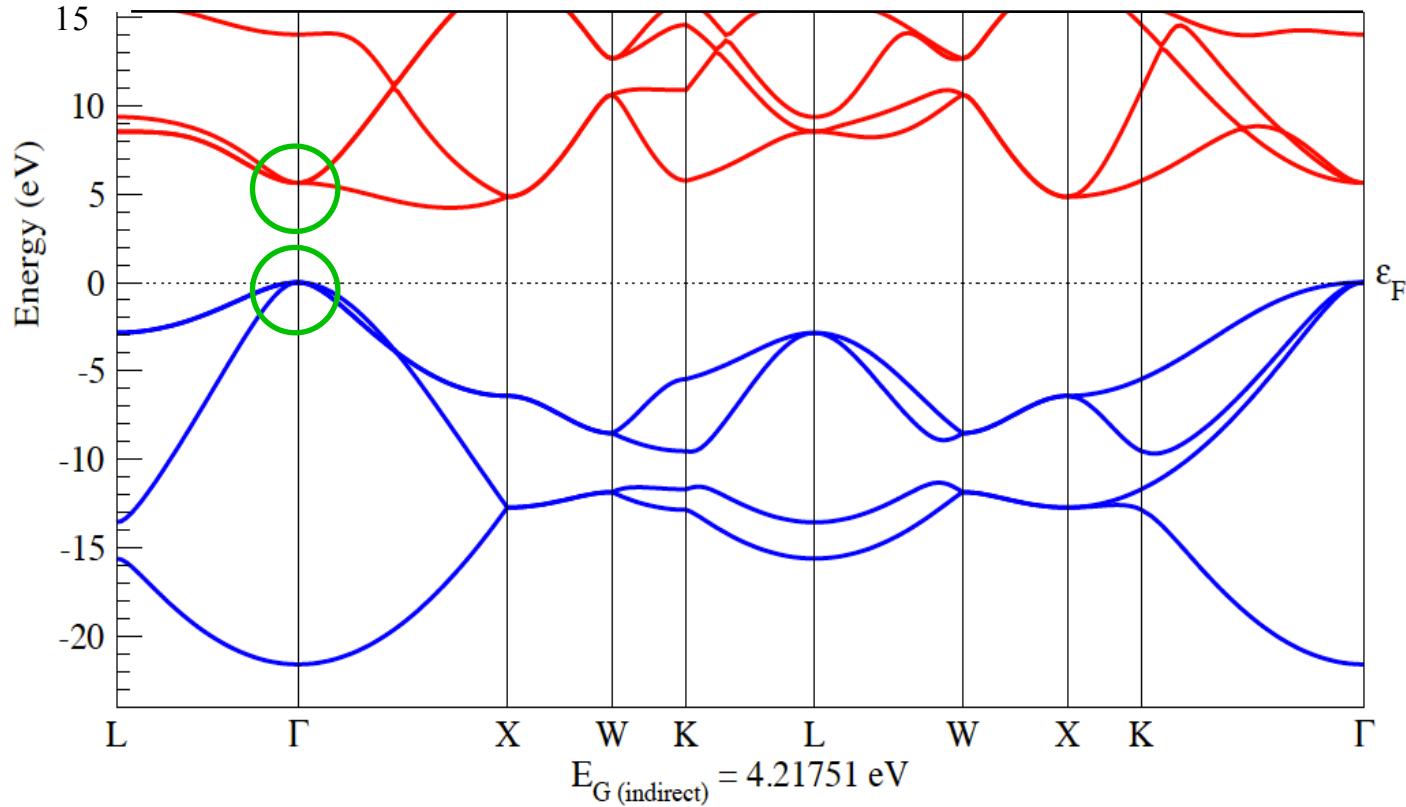
- Implementation in ABINIT ([www.abinit.org](http://www.abinit.org))
- Plane wave + pseudopotential methodology
- Converged number of plane waves (30 ... 40 Hartree)
- $k$  point sampling : 6x6x6 is sufficient for the generation of the first-order Hamiltonian
- Sampling on the  $q$  phonon wavevectors for the Fan term is a big issue !

$$\delta\epsilon_{\Gamma n}^{ZPM} = \frac{1}{N_{\vec{q}}} \sum_{\vec{q}j} \frac{\partial\epsilon_{\Gamma n}}{\partial n_{\vec{q}j}} \frac{1}{2}$$

$$\frac{\partial\epsilon_{\Gamma n}(Fan)}{\partial n_{\vec{q}j}} = \frac{1}{\omega_{\vec{q}j}} \Re \sum_{\kappa a \kappa' b n'} \frac{\langle \phi_{\Gamma n} | \nabla_{\kappa a} H_{\kappa} | \phi_{\vec{q}n'} \rangle \langle \phi_{\vec{q}n'} | \nabla_{\kappa' b} H_{\kappa'} | \phi_{\Gamma n} \rangle}{\epsilon_{\Gamma n} - \epsilon_{\vec{q}n'}} \frac{\xi_{\kappa a}(\vec{q}j) \xi_{\kappa' b}(-\vec{q}j)}{\sqrt{M_{\kappa} M_{\kappa'}}} e^{iq.(R_{\kappa' b} - R_{\kappa a})}$$

Indeed (1) interband contributions have strong variations  
(2) intraband contributions diverge due to the denominator !

# Intraband divergence for small q

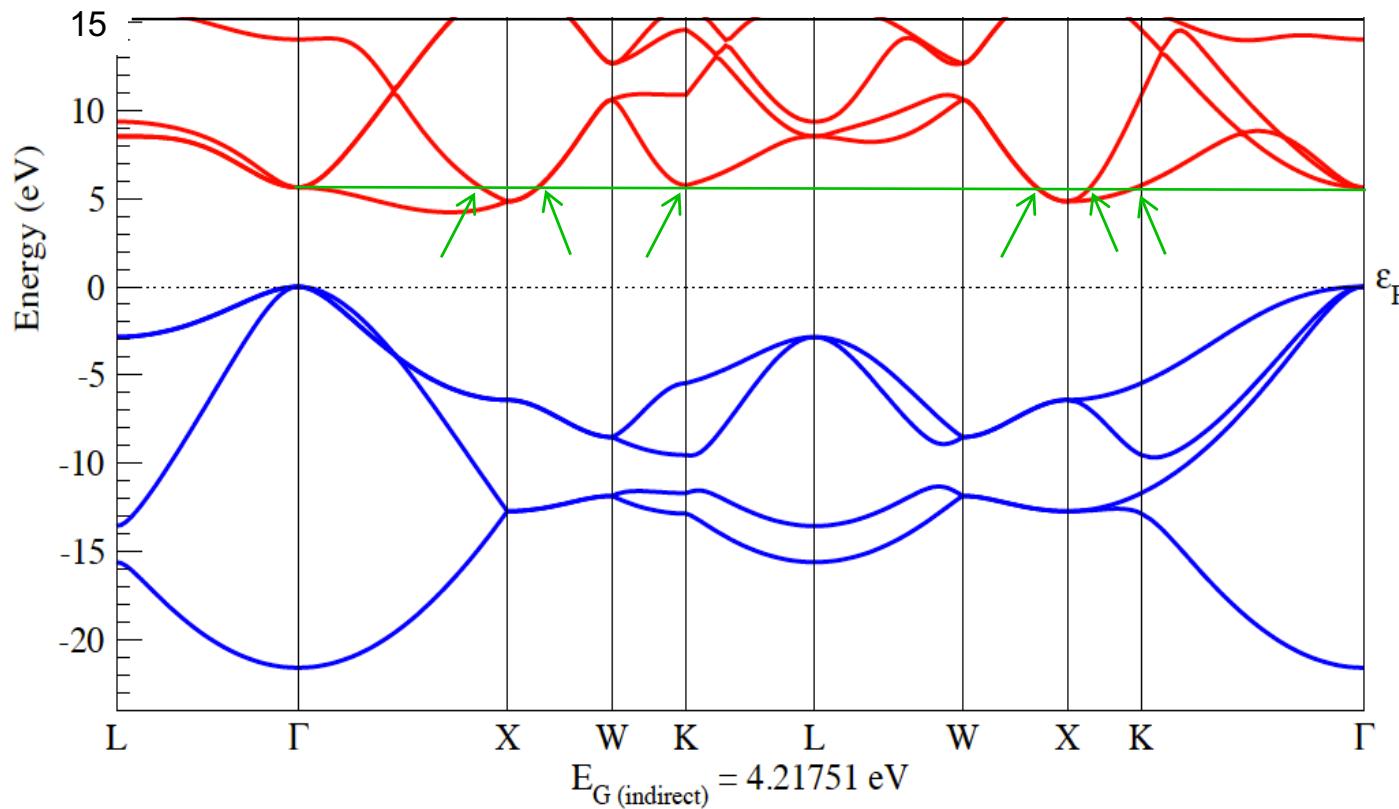


$$\lim_{\vec{q} \rightarrow 0} \frac{\partial \epsilon_{\Gamma n}(\text{Fan})}{\partial n_{\vec{q}j}} = \lim_{\vec{q} \rightarrow 0} \frac{1}{\omega_{\vec{q}j}} \frac{f(\vec{q}jn)}{\epsilon_{\Gamma n} - \epsilon_{\vec{q}n}}$$

Optic modes :  $\lim_{\vec{q} \rightarrow 0} \frac{\partial \epsilon_{\Gamma n}(\text{Fan})}{\partial n_{\vec{q}j}} \propto \frac{1}{q^2}$

However, for acoustic modes, Fan/DDW contribs cancel each other

# Intraband divergence on isoenergetic surface



Set of  
isoenergetic  
wavevectors

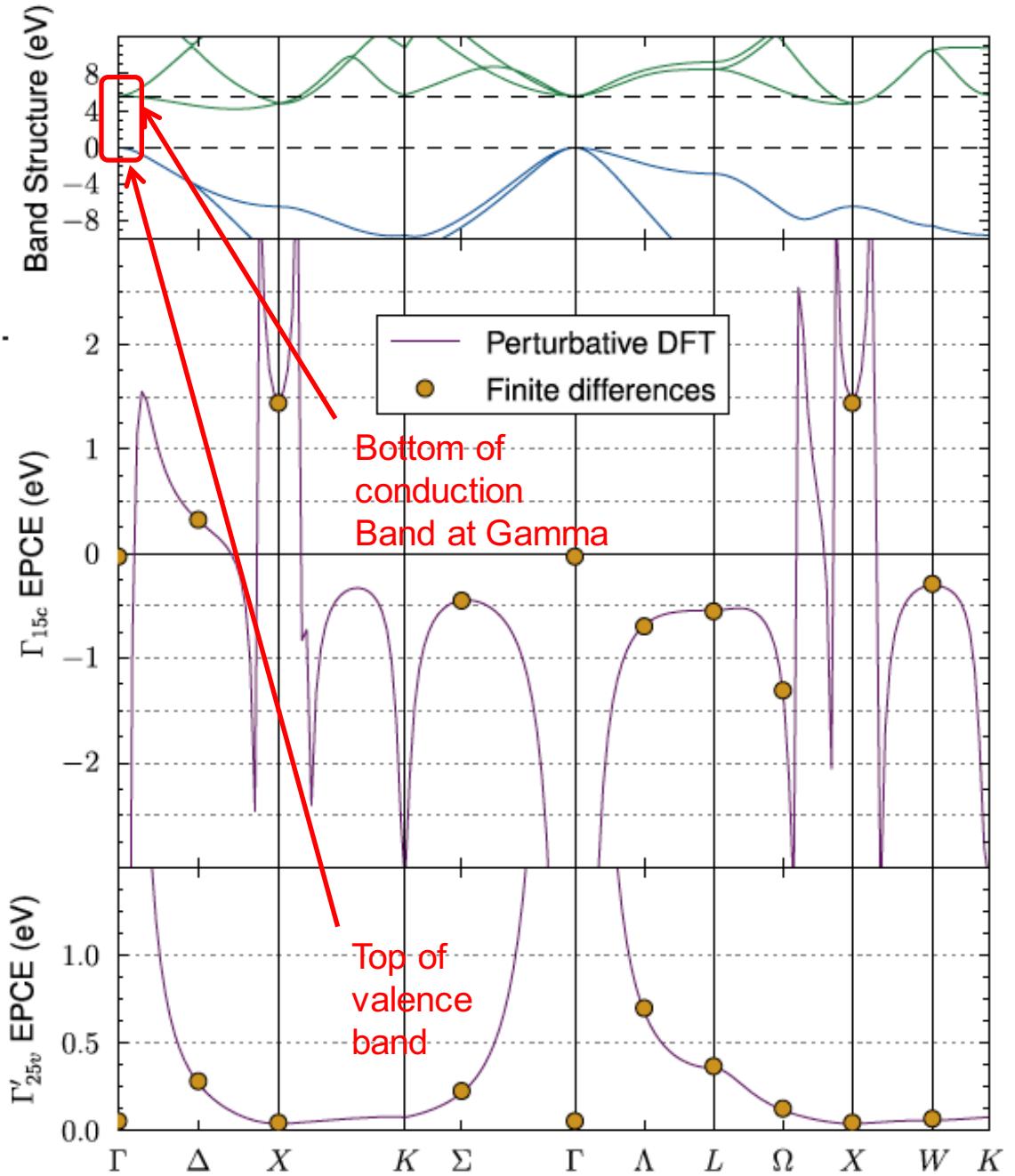
$$\lim_{\vec{q} \rightarrow \vec{q}_{iso}} \frac{\partial \epsilon_{\Gamma n}(Fan)}{\partial n_{\vec{q}j}} = \lim_{\vec{q} \rightarrow \vec{q}_{iso}} \frac{1}{\omega_{\vec{q}j}} \frac{f(\vec{q}jn)}{\epsilon_{\Gamma n} - \epsilon_{\vec{q}n}} \propto \frac{1}{\nabla_{\vec{q}} \epsilon_{\vec{q}n} \Big|_{\vec{q}_{iso}} \cdot (\vec{q} - \vec{q}_{iso})}$$

Problem only for the ZPR of the conduction state

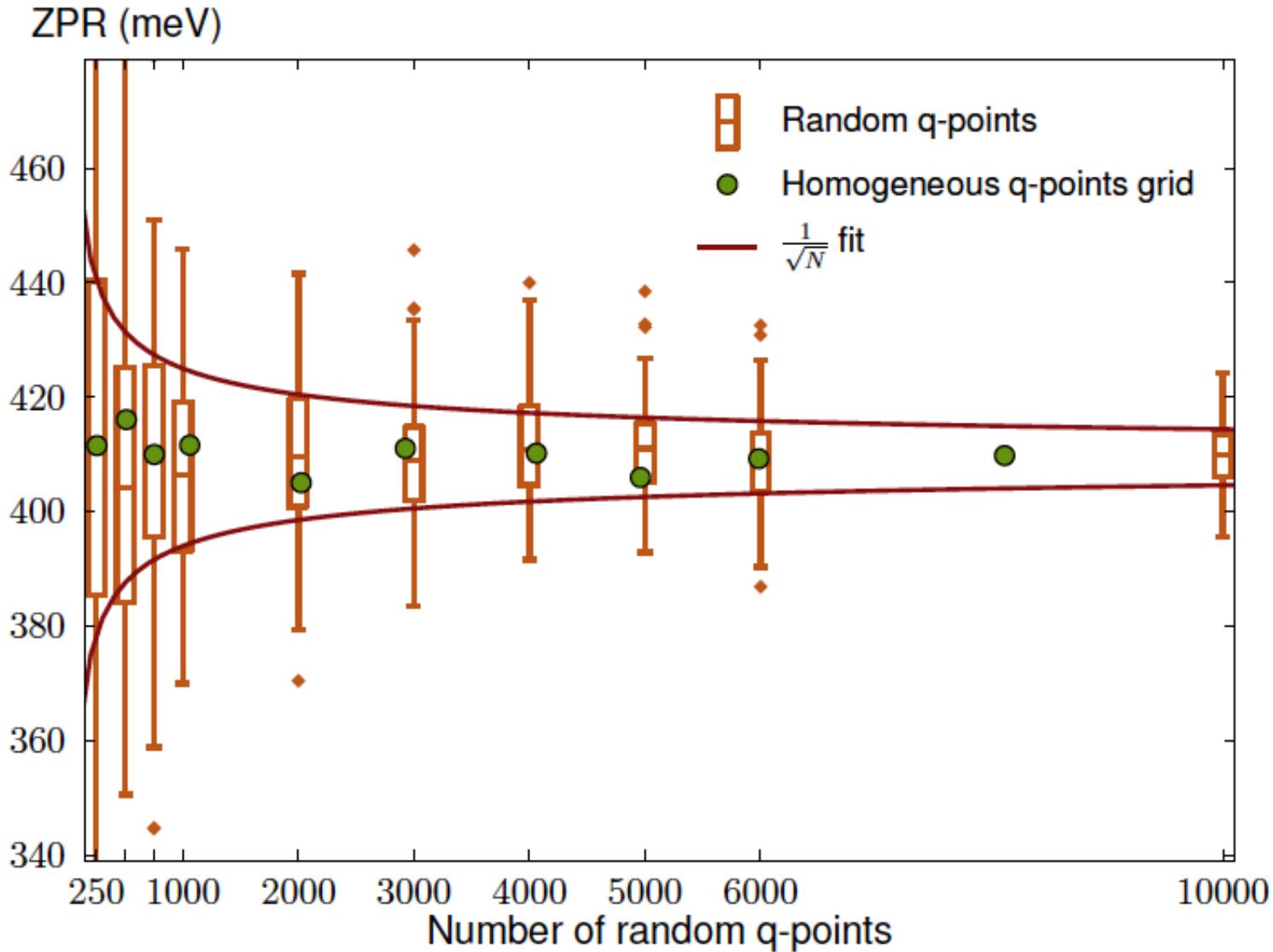
# Phonon wavevector integration

$$\delta\epsilon_{\vec{k}n}(T, V = \text{const}) = \frac{1}{N_{\vec{q}}} \sum_{\vec{q}j} \frac{\partial\epsilon_{\vec{k}n}}{\partial n_{\vec{q}j}} \left( \langle \hat{n}_{\vec{q}j} \rangle(T) + \frac{1}{2} \right)$$

G. Antonius, S. Poncé, P. Boulanger,  
 M. Côté & XG,  
*Phys. Rev. Lett.* 112, 215501 (2014)



# Rate of convergence



S. Poncé et al, Comput. Materials Science 83, 341 (2014)

# Smoothing the denominator

$$\frac{\partial \varepsilon_{\Gamma n}(Fan)}{\partial n_{\vec{q}j}} = \frac{1}{\omega_{\vec{q}j}} \Re \sum_{\kappa a \kappa' b n'} \frac{\langle \phi_{\Gamma n} | \nabla_{\kappa a} H_{\kappa} | \phi_{\vec{q}n'} \rangle \langle \phi_{\vec{q}n'} | \nabla_{\kappa' b} H_{\kappa'} | \phi_{\Gamma n} \rangle}{\varepsilon_{\Gamma n} - \varepsilon_{\vec{q}n'} + i\delta} \frac{\xi_{\kappa a}(\vec{q}j) \xi_{\kappa' b}(-\vec{q}j)}{\sqrt{M_{\kappa} M_{\kappa'}}} e^{iq.(R_{\kappa' b} - R_{\kappa a})}$$

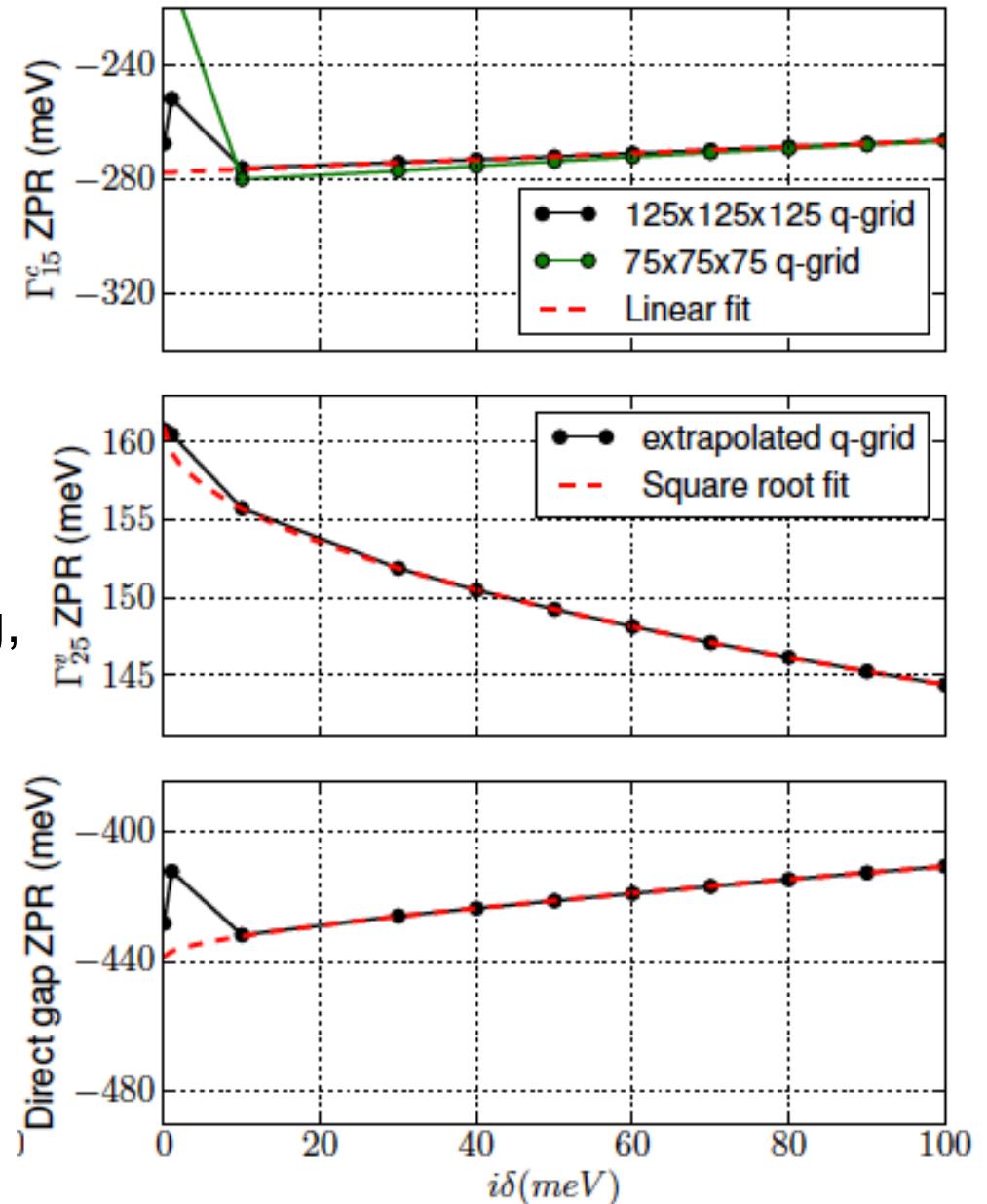
... dramatically helps the convergence ... to a (slightly) different value ...  
 If imaginary part = 100 meV :

q grid	#q in IBZ	ZPM HOMO (meV)	ZPM LUMO (meV)	ZPM gap (meV)
8x8x8 x4s	60	140.5	-181.9	-322.4
12x12x12 x4s	182	141.7	-293.1	-434.8
16x16x16 x4s	408	141.7	-273.9	-415.6
20x20x20 x4s	770	141.7	-260.1	-401.8
24x24x24 x4s	1300	141.7	-257.5	-399.2
28x28x28 x4s	2030	141.7	-269.1	-410.8
32x32x32 x4s	2992	141.7	-271.8	-413.5

# Changing the imaginary delta

$$\frac{f(\vec{q}jn)}{\epsilon_{\Gamma n} - \epsilon_{\vec{q}n} + i\delta}$$

For very large q-wavevector sampling,  
rate of convergence understood,  
+ correspond to expectations !



# Cross-checking

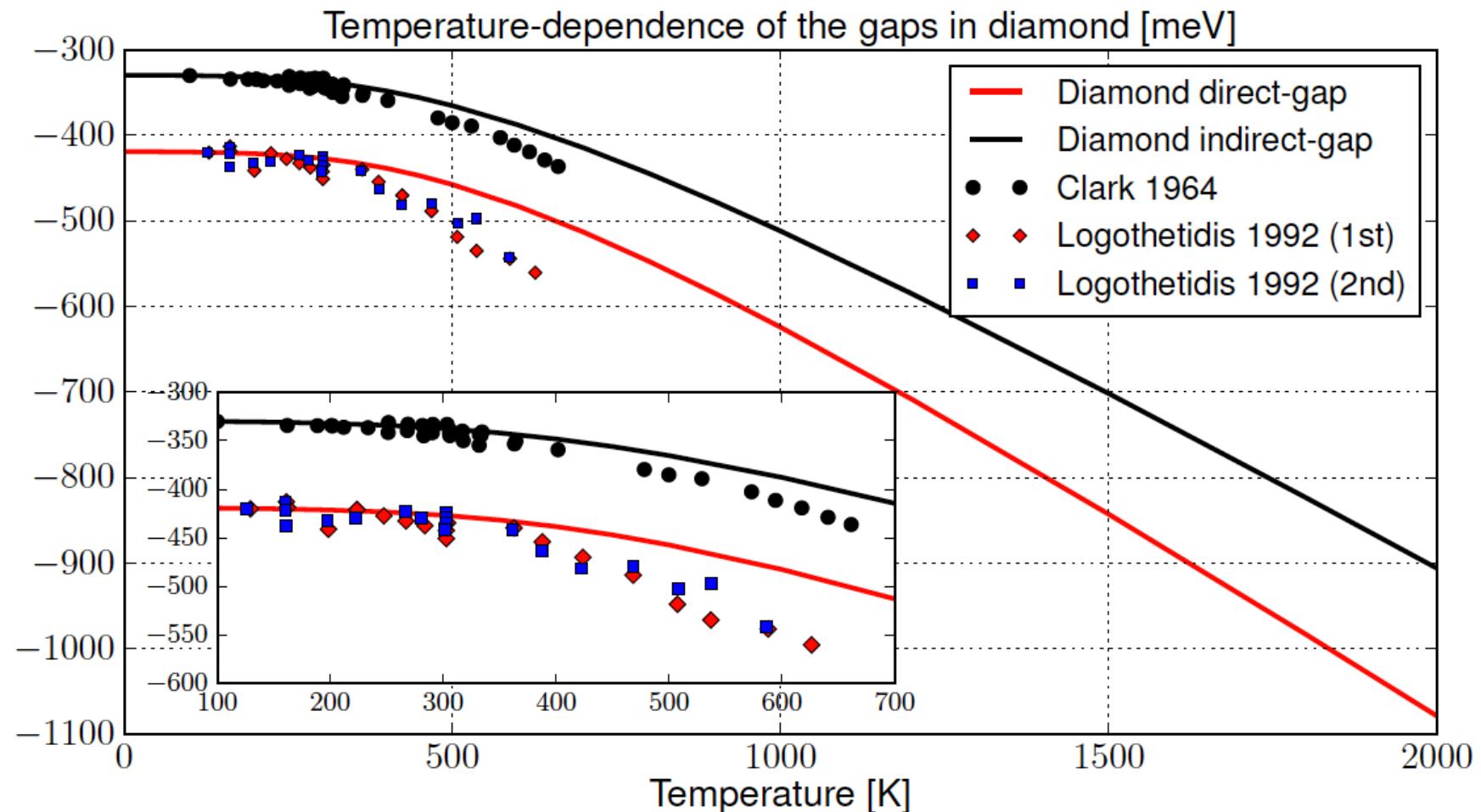
Independent implementations (without the Sternheimer trick, though)

- Quantum/Espresso + EPW => 0.6 eV ... ?! (*Giustino, PRL105, 265501 (2010)*)
- Quantum/Espresso + Yambo => initially 0.6 eV, but after debugging, excellent agreement with ABINIT ... 0.4 eV !

Band	Fan + DDW	
	ABINIT 7.3.2 SEq/ 300 bands	Yambo 3.4.0 300 bands
1	-61.75	-61.87
2-3-4	140.54	140.70
5-6-7	-260.63	-259.40
8	-232.37	-230.40
9	-43.86	-43.95
ZPR Band gap	-401.17 meV	-400.10 meV

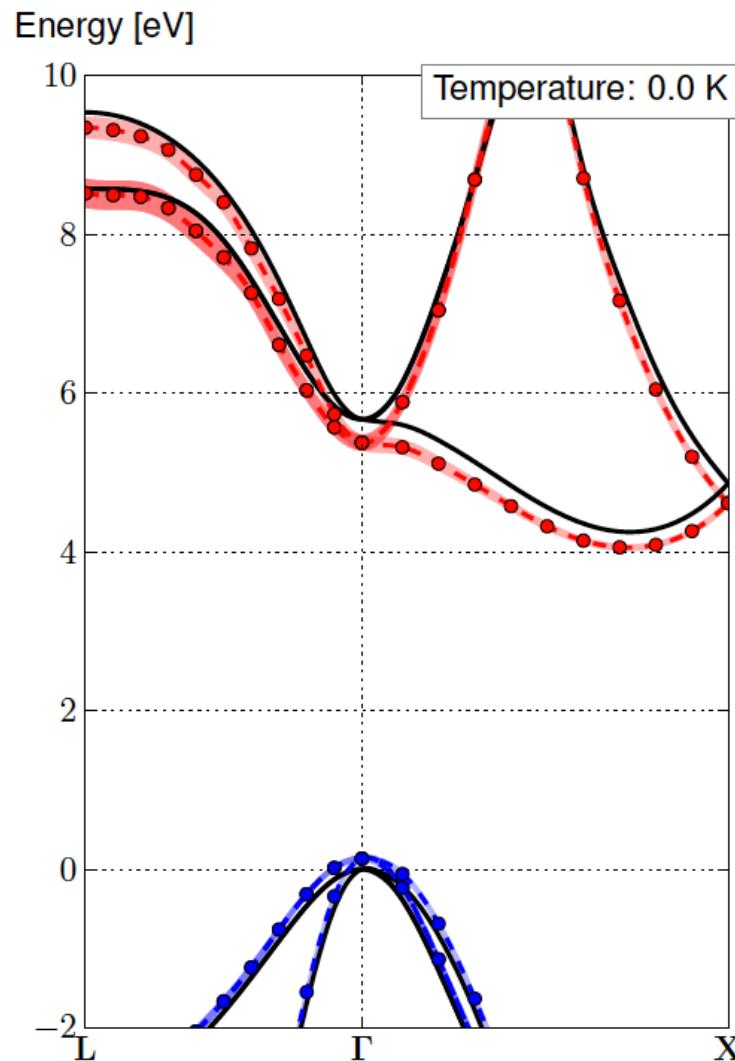
S. Poncé et al, *Comput. Materials Science* 83, 341 (2014)

# DFT+AHC T-dependent bandgap : diamond



Not bad, but still too small effect ... ?!

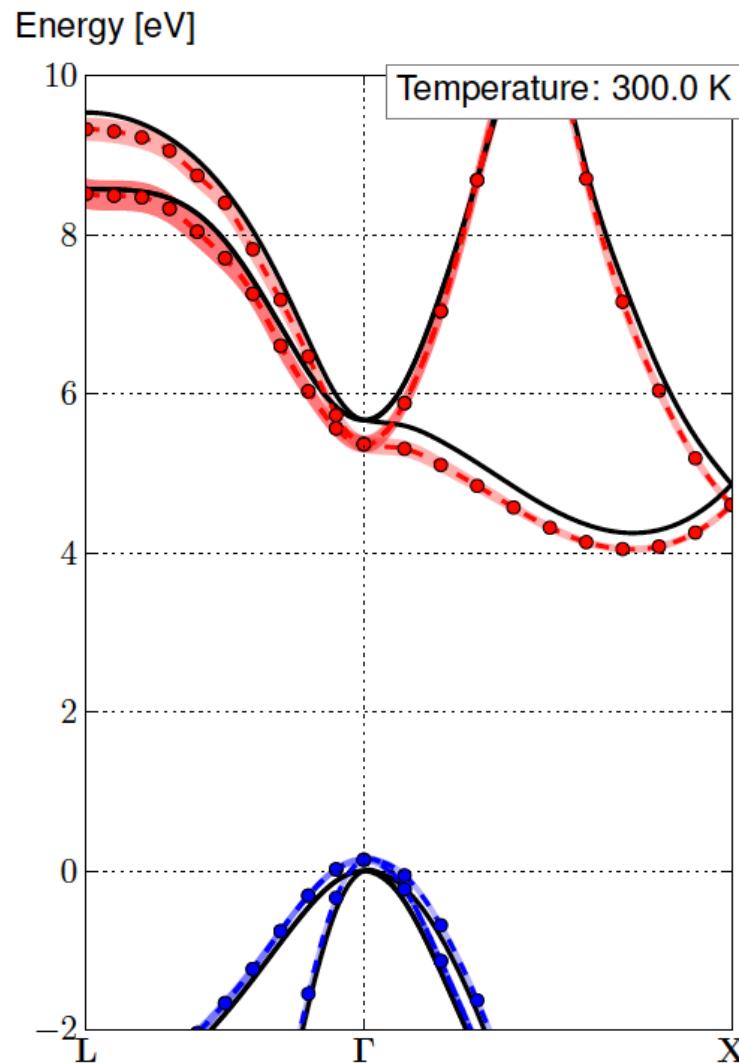
# DFT T-dependent band structure



Diamond 0 Kelvin  
(incl. Zero-point motion)

Note the widening of  
the bands = lifetime

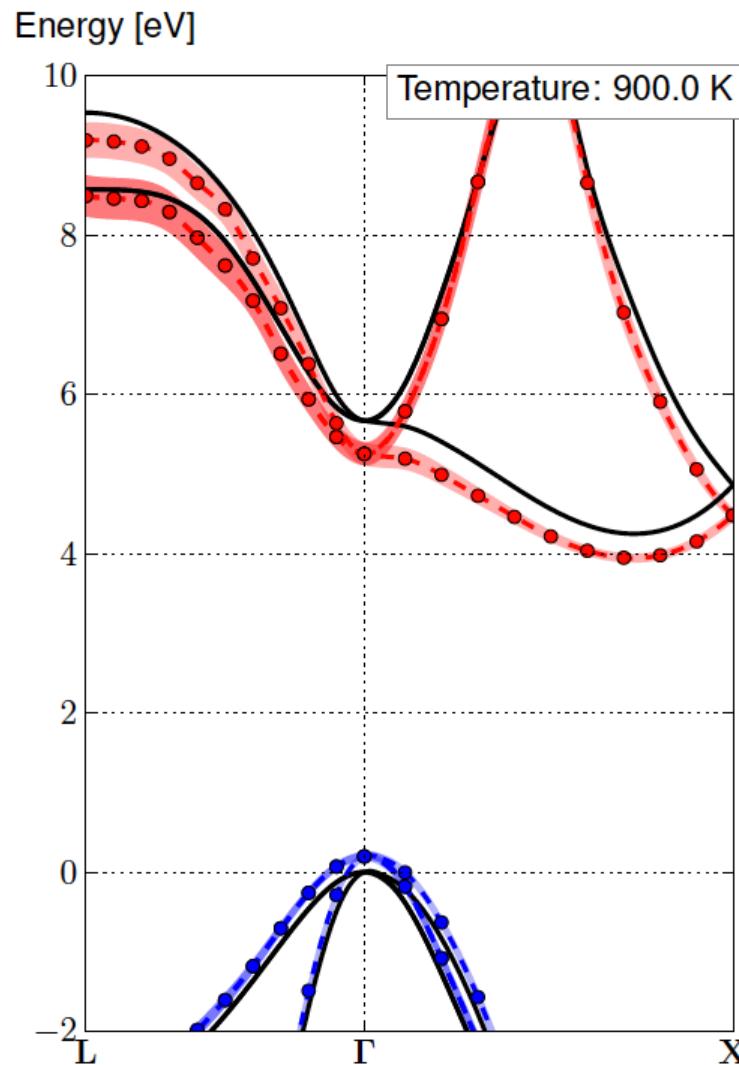
# DFT T-dependent band structure



Diamond 300 Kelvin

Note the widening of  
the bands = lifetime

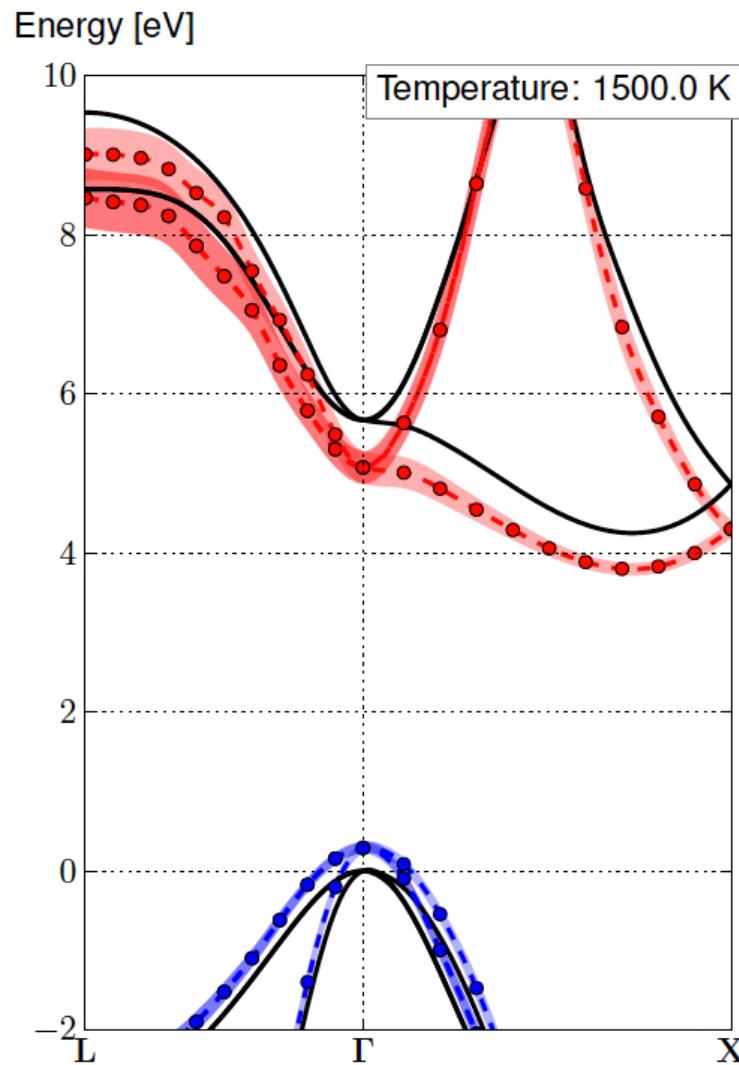
# DFT T-dependent band structure



Diamond 900 Kelvin

Note the widening of  
the bands = lifetime

# DFT T-dependent band structure



Diamond 1500 Kelvin

Note the widening of  
the bands = lifetime

# Temperature effects with GW electronic structure

# GW energies + frozen-phonon in supercells

$$\delta\epsilon_{\vec{k}n}(T, V = \text{const}) = \frac{1}{N_{\vec{q}}} \sum_{\vec{q}j} \frac{\partial\epsilon_{\vec{k}n}}{\partial n_{\vec{q}j}} \left( \langle \hat{n}_{\vec{q}j} \rangle(T) + \frac{1}{2} \right)$$

+ occupation number  
from Bose-Einstein  
statistics

$$\frac{\partial\epsilon_{\vec{k}n}}{\partial n_{\vec{q}j}} = \frac{1}{2\omega_{\vec{q}j}} \sum_{\kappa a \kappa' b} \frac{\partial^2 \epsilon_{\vec{k}n}}{\partial R_{\kappa a} \partial R_{\kappa' b}} \frac{\xi_{\kappa a}(\vec{q}j) \xi_{\kappa' b}(-\vec{q}j)}{\sqrt{M_\kappa M_{\kappa'}}} e^{iq.(R_{\kappa' b} - R_{\kappa a})}$$



Finite-difference evaluation of the derivatives  
of the **GW** electronic energies wrt phonons,  
using supercells

G. Antonius, S. Poncé, P. Boulanger, M. Côté & XG, *Phys. Rev. Lett.* 112, 215501 (2014)

# Electron-phonon coupling energies

EPCE

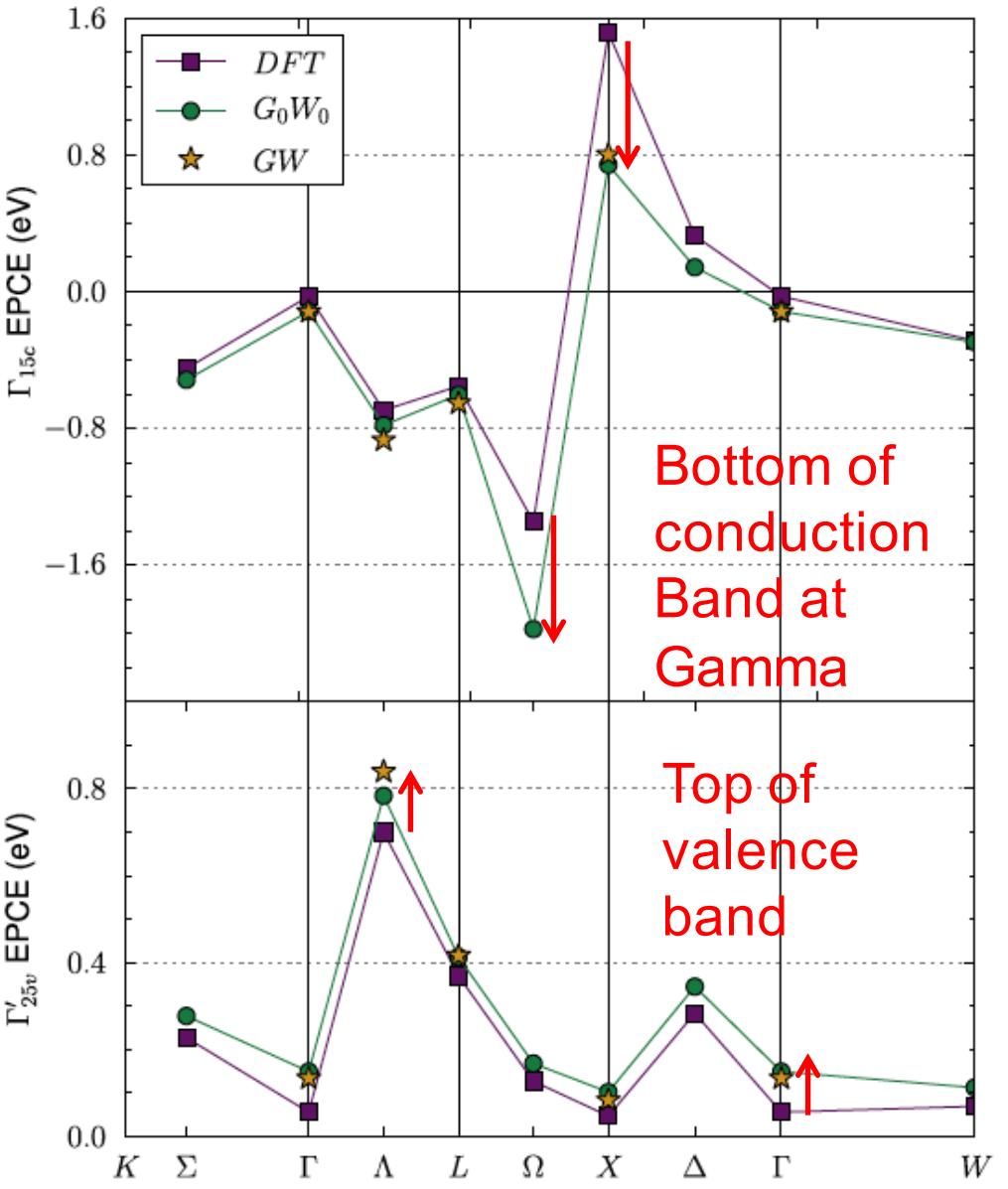
$$\frac{\partial \mathcal{E}_{\vec{k}n}}{\partial n_{\vec{q}j}}$$

from DFT, G0W0  
and scGW

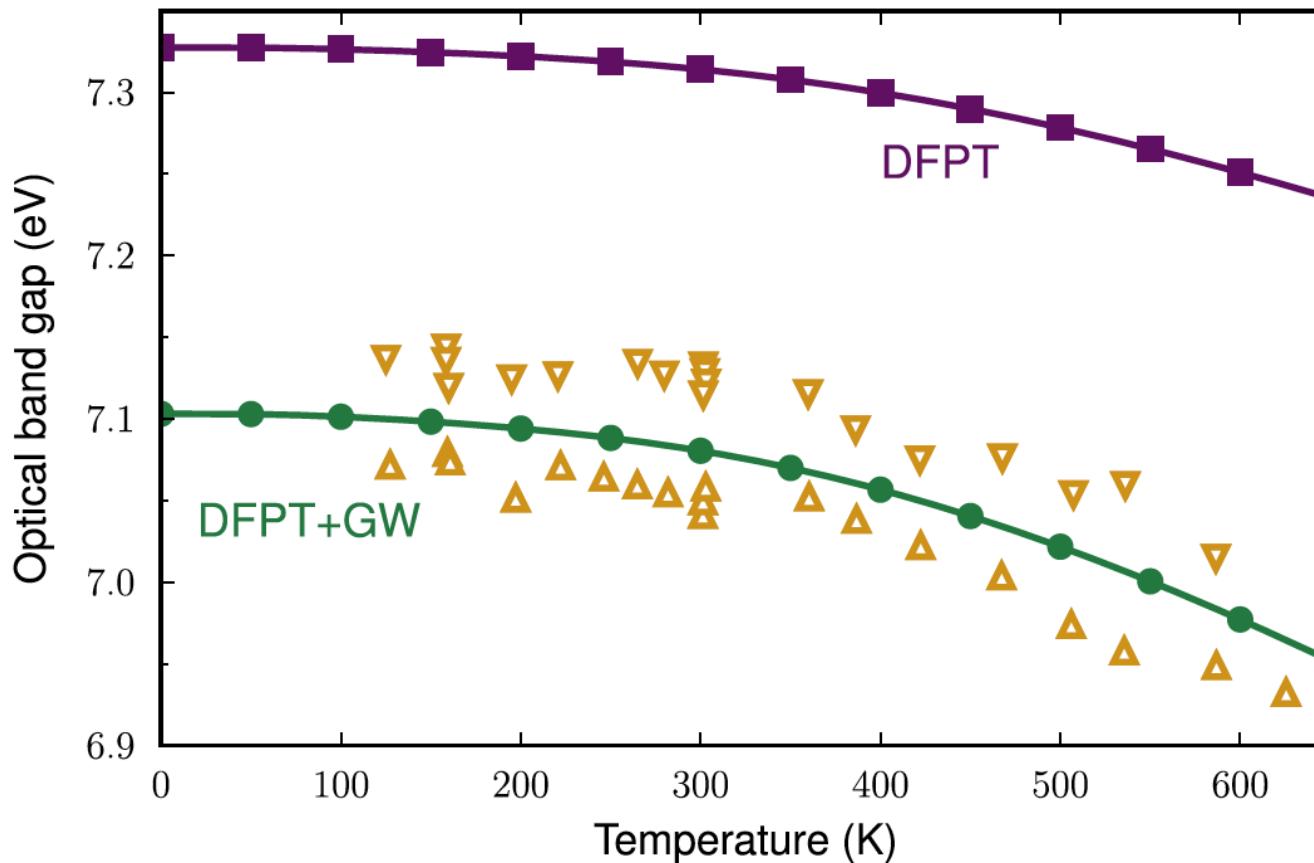
Significantly larger decrease of  
the gap within G0W0 and scGW  
compared to DFT

G0W0 and scGW very close  
to each other

G. Antonius, S. Poncé, P. Boulanger, M. Côté & XG,  
*Phys. Rev. Lett.* 112, 215501 (2014)



# DFT + perturbative phonons + GW + frozen-phonon in supercells

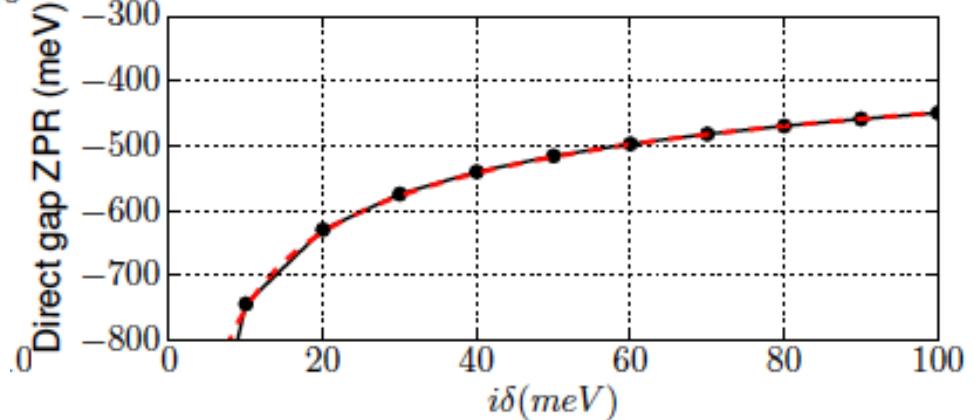
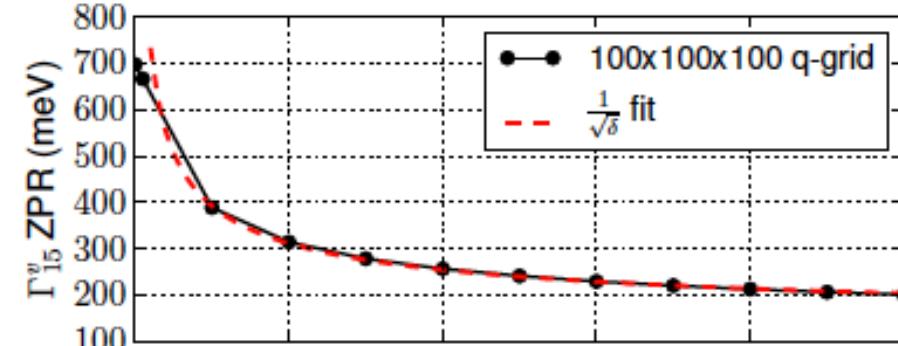
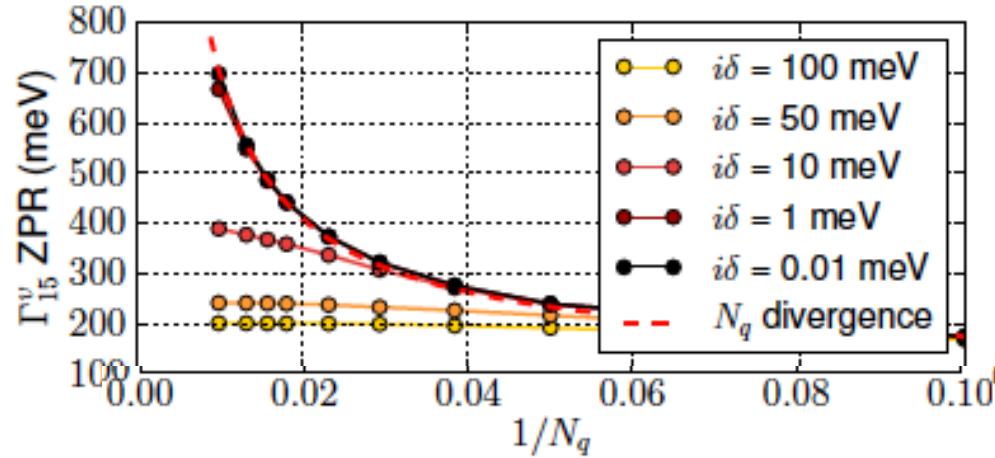


Zero-point motion  
in DFT :  
0.4 eV  
for the direct gap

Zero-point motion  
in DFT+GW :  
0.63 eV  
for the direct gap,  
in agreement  
with experiments

# **Breakdown of the adiabatic AHC theory for infra-red active materials**

# Boron nitride renormalization of gap



when the imaginary delta  
tends to zero,  
the ZPR diverges !

... such a divergence is confirmed  
by a « post-mortem » analysis ...

# Electric field with IR-active optic modes

Collective displacement with wavevector  $|\mathbf{q}| \rightarrow 0$

$$H_{\mathbf{q}}^{(1)} = \bar{V}_{ext,\mathbf{q}}^{(1)} + \bar{V}_{H,\mathbf{q}}^{(1)} + \bar{V}_{xc,\mathbf{q}}^{(1)}$$

$$\bar{V}_{ext,\mathbf{q}}^{(1)}(\mathbf{G}) = \frac{-i}{\Omega_0} (\mathbf{G} + \boxed{\mathbf{q}})_{\alpha} e^{-i(G+q)\cdot\tau} v_{\kappa}(\mathbf{G} + \mathbf{q})$$

$$v_{\kappa}(\mathbf{q} \rightarrow 0) = -\frac{4\pi Z_{\kappa}}{\boxed{q^2}} + C_{\kappa} + O(q^2)$$

$$\bar{V}_{H,\mathbf{q}}^{(1)}(\mathbf{G}) = 4\pi \frac{\bar{n}_{\mathbf{q}}^{(1)}}{|\mathbf{G} + \boxed{\mathbf{q}}|^2}$$

$$\bar{n}_{\mathbf{q}}^{(1)} \propto |\mathbf{q}| \text{ when } |\mathbf{q}| \rightarrow 0$$

Both the “external” and Hartree potentials can diverge like  $\boxed{1/q}$ .

Definition of the polarization of a phonon mode :  $P_{\alpha}^{(1)}(\mathbf{q}j) = \sum_{\kappa\beta} Z_{\kappa,\alpha\beta}^* \xi_{\kappa\beta}(\mathbf{q}j)$

$$Z_{\kappa,\alpha\beta}^* = \Omega_0 \left. \frac{\partial P_{\alpha}}{\partial u_{\kappa,\beta}} \right|_{\delta\vec{E}=0}$$

Born effective charge tensor for atom  $K$

$$\text{Associated electric field } E_{\alpha} = -\frac{4\pi}{\Omega_0} \frac{\sum_{\delta} P_{\delta}^{(1)}(\mathbf{q}j) q_{\delta}}{\sum_{\gamma\delta} q_{\gamma} \epsilon_{\gamma\delta} q_{\delta}} = i H_{\mathbf{q}}^{(1)}(\mathbf{G} = 0)$$

# AHC with IR-active optic modes

$$\frac{\partial \varepsilon_{\Gamma n}(Fan)}{\partial n_{\vec{q}j}} = \frac{1}{\omega_{\vec{q}j}} \Re \sum_{\kappa a \kappa' b n'} \frac{\langle \phi_{\Gamma n} | \nabla_{\kappa a} H_{\kappa} | \phi_{\vec{q}n'} \rangle \langle \phi_{\vec{q}n'} | \nabla_{\kappa' b} H_{\kappa'} | \phi_{\Gamma n} \rangle}{\varepsilon_{\Gamma n} - \varepsilon_{\vec{q}n'}} \frac{\xi_{\kappa a}(\vec{q}j) \xi_{\kappa' b}(-\vec{q}j)}{\sqrt{M_{\kappa} M_{\kappa'}}} e^{iq.(R_{\kappa' b} - R_{\kappa a})}$$

$$H_{\vec{q}}^{(1)} = \sum_{\kappa a} \nabla_{\kappa a} H_{\kappa} \xi_{\kappa a}(\vec{q}j) \quad \text{diverges like } 1/q \text{ for polar optic modes.}$$

At band extrema, the denominator diverges like  $1/q^2$ .

For non-polar modes, divergence like  $1/q^2$ , can be integrated ...

For polar optic modes, divergence like  $1/q^4$ , cannot be integrated ...

The adiabatic AHC theory breaks down for materials with IR-active optic modes. Also harmonic thermal average method !

[ Note : In gapped systems, only elemental solids do not have IR-active modes]

# Non-adiabatic AHC theory

Beyond Rayleigh-Schrödinger perturbation theory ... MBPT !

Fan self-energy :

$$\Sigma_{\lambda\lambda'}^{Fan}(\omega) = \sum_{\nu} \frac{1}{2\omega_{\nu}} \sum_{\lambda''} \langle \psi_{\lambda} | H_{\nu}^{(1)} | \psi_{\lambda''} \rangle \langle \psi_{\lambda''} | H_{\nu}^{(1)*} | \psi_{\lambda'} \rangle$$
$$\left[ \frac{n_{\nu}(T) + f_{\lambda''}(T)}{\omega - \varepsilon_{\lambda''}^0 + \omega_{\nu} + i\eta \operatorname{sgn}(\omega)} + \frac{n_{\nu}(T) + 1 - f_{\lambda''}(T)}{\omega - \varepsilon_{\lambda''}^0 - \omega_{\nu} + i\eta \operatorname{sgn}(\omega)} \right]$$

This yields a renormalizable theory !

Different levels :

On-the-mass shell approximation  $\varepsilon_{\lambda} = \varepsilon_{\lambda}^0 + \Sigma_{\lambda}^{ep}(\varepsilon_{\lambda}^0)$

Quasi-particle approximation  $\varepsilon_{\lambda} = \varepsilon_{\lambda}^0 + \Sigma_{\lambda}^{ep}(\varepsilon_{\lambda})$   $\varepsilon_{\lambda} = \varepsilon_{\lambda}^0 + Z_{\lambda} \Sigma_{\lambda}^{ep}(\varepsilon_{\lambda}^0)$

$$Z_{\lambda} = \left( 1 - \Re e \frac{\partial \Sigma_{\lambda}^{ep}(\omega)}{\partial \omega} \Big|_{\omega=\varepsilon_{\lambda}^0} \right)^{-1}$$

Or even spectral functions

$$A_{\lambda}(\omega) = \frac{1}{\pi} \frac{|\Im m \Sigma_{\lambda}^{ep}(\omega)|}{[\omega - \varepsilon_{\lambda}^0 - \Re e \Sigma_{\lambda}^{ep}(\omega)]^2 + |\Im m \Sigma_{\lambda}^{ep}(\omega)|^2}$$

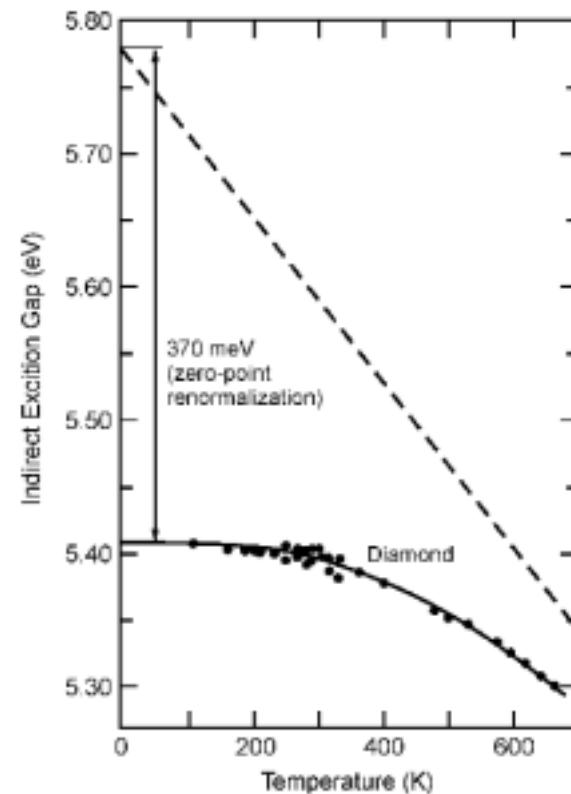
S. Poncé, Y. Gillet, J. Laflamme Janssen, A. Marini,  
M. Verstraete & XG, J. Chem. Phys. 143, 102813 (2015)

# T-dependent bandgaps for several insulators

Zero-temperature limit  
and  
High-temperature linear slope

$$\varepsilon_\lambda = \varepsilon_\lambda^0 + \Sigma_\lambda^{ep}(\varepsilon_\lambda^0)$$

S. Poncé, Y. Gillet, J. Laflamme Janssen, A. Marini,  
M. Verstraete & XG, J. Chem. Phys. 143, 102813 (2015)



Compounds	Gap	Static	ZPR [meV]	$(d\text{Gap}/dT)_{T \rightarrow \infty}$ [meV/K]	
			Non-adiabatic	Experimental	Non-adiabatic
$\alpha$ -AlN	$\Gamma - \Gamma$	-	-377.7	-239 <sup>[62]</sup>	-0.83 <sup>[53][55][62]</sup>
$\beta$ -AlN	$\Gamma - \Gamma$	-	-413.6		-0.763
	$\Gamma - \text{X}$	-	-334.4		-0.521
c-BN	$\Gamma - \Gamma$	-	-502.0		-0.639
	$\Gamma - \text{X}$	-	-405.6		-0.521
C	$\Gamma - \Gamma$	-438.6	-415.8	-320 <sup>[52]</sup> , -450 <sup>[52]</sup>	-0.504
	$\Gamma - 0.727\text{X}$	-379.3	-329.8	-364 <sup>[53]</sup>	-0.435
Si	$\Gamma - \Gamma$	-47.1	-42.1		-0.147
	$\Gamma - 0.848\text{X}$	-64.3	-56.2	-62 <sup>[53]</sup> , -64 <sup>[53]</sup>	-0.32 <sup>[58][59]</sup>

# Dynamical ep renormalisation for 4 solids

On top of DFT : from static AHC ( $\delta=0.1$  eV), to position of peak maximum

		$\Sigma^{stat}(\varepsilon^0)$	$\Sigma^{dyn}(\varepsilon^0)$	$Z$	$Z\Sigma^{dyn}(\varepsilon^0)$	$\Sigma^{dyn}(\varepsilon)$	$\Delta A(\varepsilon)$
C	VB	0.134	0.126	0.931	0.118	0.118	0.118
	CB	-0.238	-0.240	1.007	-0.242	-0.240	-0.247
	Gap	-0.372	-0.366	-	-0.359	-0.358	-0.365
BN	VB	0.198	0.173	0.823	0.143	0.147	0.147
	CB	-0.190	-0.196	1.020	-0.200	-0.197	-0.208
	Gap	-0.388	-0.370	-	-0.343	-0.344	-0.355
MgO	VB	0.197	0.198	0.734	0.145	0.145	0.147
	CB	-0.153	-0.143	0.870	-0.125	-0.127	-0.127
	Gap	-0.350	-0.341	-	-0.270	-0.272	-0.274
LiF	VB	0.398	0.446	0.596	0.266	0.254	0.256
	CB	-0.279	-0.273	0.746	-0.204	-0.211	-0.211
	Gap	-0.677	-0.718	-	-0.469	-0.464	-0.467

$$Z_\lambda = \left( 1 - \Re \frac{\partial \Sigma_\lambda^{ep}(\omega)}{\partial \omega} \Big|_{\omega=\varepsilon_\lambda^0} \right)^{-1}$$



From peak max  
of spectral function

# Advertisement for ABINIT v8.0.7

ABINIT v8.0.x recently made available (1 year of cleaning and new devs).

New features (or much improved features) :

- Temperature-dependence of the electronic structure
- Dynamical-Mean Field Theory (CT-QMC solver and TRIQS library)
- Van der Waals (DFT-Dx , also including phonons)
- Improved Bethe-Salpeter (recursion, direct diag, CG + interpolation)
- PIMD
- Pseudos and PAW atomic data : well-tested tables (see Lejaeghere et al 2016)

In addition to already existing features :

- DFPT (with NC and PAW) also for direct eval of effective masses
- GW
- Finite electric field + Berry phase
- ...

See <http://www.abinit.org> , including the tutorial, and  
XG et al , Comput. Phys. Comm. 205, 106 (2016)

# A few more data - all within DFT - ...

*...Not of equivalent quality ... Different approximations ...*

## Big shifts :

CH <sub>4</sub> crystal	1.7 eV	
NH <sub>3</sub> crystal	1.0 eV	
Ice	1.5 eV	
HF crystal	1.6 eV	(Montserrat et al, 2015)
Helium (at 25 TPa)	2.0 eV	(Montserrat et al, 2014)

## Medium shifts :

Helium (at 0 GPa)	0.40 eV	(Montserrat, Conduit, Needs, 2013)
LiNbO <sub>3</sub>	0.41 eV	(Friedrich et al, 2015)
Polyethylene	0.28 eV	(Canuccia & Marini, 2012)

## Small shifts :

LiH	0.04 eV	
LiD	0.03 eV	(Montserrat, Drummond, Needs, 2013)
GaN	0.13 eV	(Kawai et al, 2013)
GaN	0.15 eV	(Nery & Allen, arXiv:1603.04269, 2016)
Trans-polyacetylene	0.04 eV	(Canuccia & Marini, 2012)

# Many-body theory with vibrational effects

# Motivation

Incoherent many-body approaches !

Either :

MBPT for electrons and EPCE (GW) +

static treatment of self-energy due to ep coupling

Or :

DFT for electrons and EPCE +

dynamical treatment of self-energy due to ep coupling

Need a unified theory.

In particular: avoid possible double counting,  
because phonons are already determined self-consistently,  
with screening. And the EPCE is also screened by electrons !

$$\Sigma_{\lambda\lambda'}^{F\,an}(\omega) = \sum_{\nu} \frac{1}{2\omega_{\nu}} \sum_{\lambda''} \langle \psi_{\lambda} | H_{\nu}^{(1)} | \psi_{\lambda''} \rangle \langle \psi_{\lambda''} | H_{\nu}^{(1)*} | \psi_{\lambda'} \rangle$$
$$\left[ \frac{n_{\nu}(T) + f_{\lambda''}(T)}{\omega - \varepsilon_{\lambda''}^0 + \omega_{\nu} + i\eta \operatorname{sgn}(\omega)} + \frac{n_{\nu}(T) + 1 - f_{\lambda''}(T)}{\omega - \varepsilon_{\lambda''}^0 - \omega_{\nu} + i\eta \operatorname{sgn}(\omega)} \right]$$

$$H_{\vec{q}}^{(1)} = \bar{V}_{ext,\vec{q}}^{(1)} + \bar{V}_{H,\vec{q}}^{(1)} + \bar{V}_{xc,\vec{q}}^{(1)}$$

# Outline

For details see :

A. Marini, S. Poncé and XG, Phys. Rev. B 91, 224310 (2015)

$$\widehat{H}(\mathbf{R}) = \widehat{H}_e + \widehat{H}_n(\mathbf{R}) + \widehat{W}_{e-n}(\mathbf{R})$$

$$\widehat{H}_e = \widehat{T}_e + \widehat{W}_{e-e}$$

$$\widehat{H}_n(\mathbf{R}) = \widehat{T}_n + \widehat{W}_{n-n}(\mathbf{R})$$

We would like :

$$\widehat{H}(\mathbf{R}) = \widehat{H}_0(\mathbf{R}) + \Delta\widehat{H}(\mathbf{R})$$

$$\widehat{H}_0(\mathbf{R}) = \sum_{n\mathbf{k}} \epsilon_{n\mathbf{k}} \hat{c}_{n\mathbf{k}}^\dagger \hat{c}_{n\mathbf{k}} + \sum_{\mathbf{q}\lambda} \omega_{\mathbf{q}\lambda} \left( \hat{b}_{\mathbf{q}\lambda}^\dagger \hat{b}_{\mathbf{q}\lambda} + \frac{1}{2} \right)$$

With physically meaningful « bare »  
electronic and phononic eigenenergies ...

# Choosing a reference system

Definition of the reference Hamiltonian (e.g. from DFT, but not mandatory)

- equilibrium atomic positions
- reference interatomic force constants

$$\hat{H}_0(\mathbf{R}) = \hat{T}_e + \hat{T}_n + \hat{W}_{e-n}(\bar{\mathbf{R}}) + \hat{W}_{n-n}(\bar{\mathbf{R}}) + \Delta \hat{W}_{n-n}^{\text{ref}}(\mathbf{R})$$

where  $\hat{W}_{e-n}$  and  $\hat{W}_{n-n}$  are evaluated at the equilibrium geometry

$$\Delta \hat{W}_{n-n}^{\text{ref}}(\mathbf{R}) = \frac{1}{2} \sum_{ls\alpha, l's'\beta} \overline{\partial_{R_{ls\alpha} R_{l's'\beta}}^2 E^{\text{BO}}(\mathbf{R})} \Delta \hat{R}_{ls\alpha} \Delta \hat{R}_{l's'\beta}$$

Remaining terms, up to 2<sup>nd</sup> order in atomic displacement operator

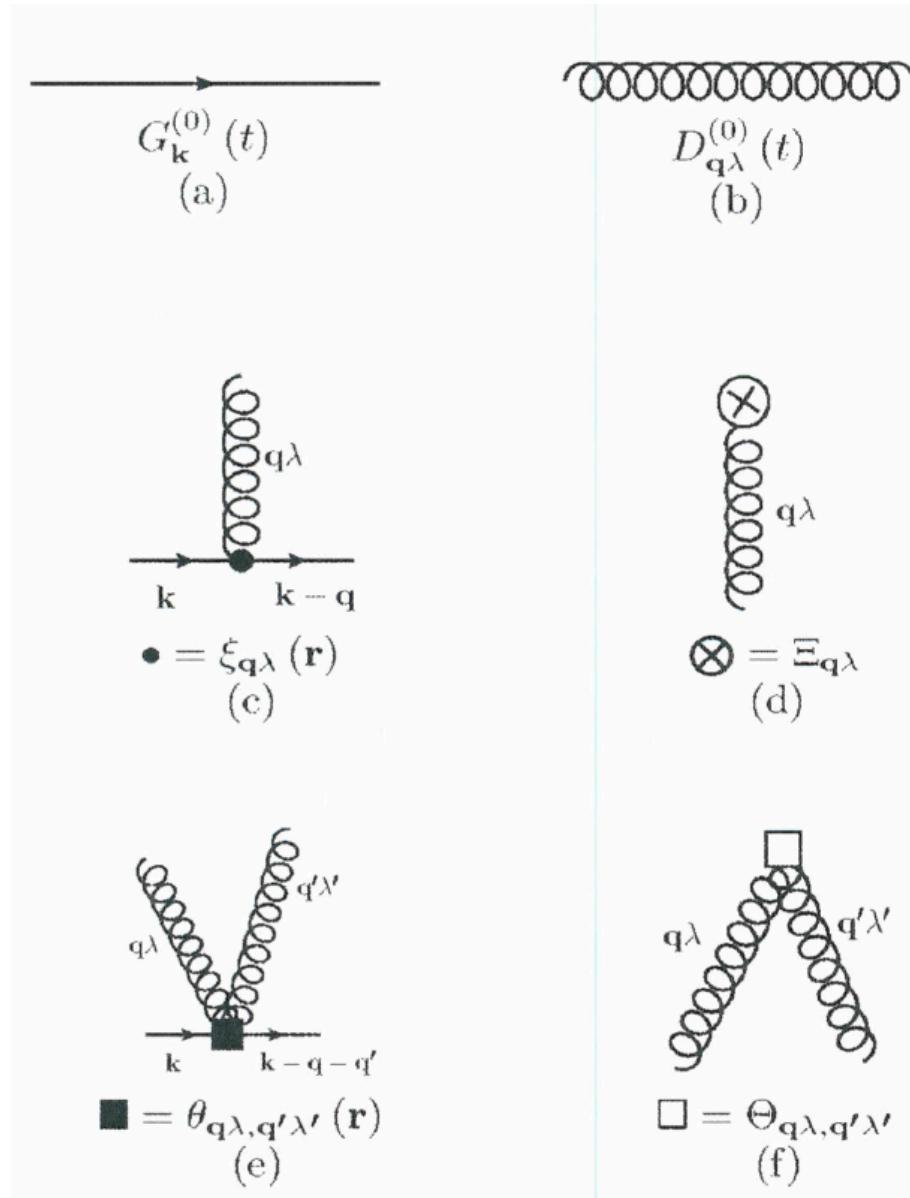
$$\Delta \hat{H}(\mathbf{R}) = \hat{W}_{e-e} + \Delta \hat{H}^{(1)}(\mathbf{R}) + \Delta \hat{H}^{(2)}(\mathbf{R})$$

$$\Delta \hat{H}^{(1)}(\mathbf{R}) \equiv \sum_{ls\alpha} \overline{\partial_{R_{ls\alpha}} [W_{e-n}(\mathbf{R}) + W_{n-n}(\mathbf{R})]} \Delta \hat{R}_{ls\alpha}$$

$$\Delta \hat{H}^{(2)}(\mathbf{R}) \equiv \frac{1}{2} \sum_{ls\alpha, l's'\beta} \overline{\partial_{R_{ls\alpha} R_{l's'\beta}}^2 [W_{e-n}(\mathbf{R}) + W_{n-n}(\mathbf{R})]}$$

$$\times \Delta \hat{R}_{ls\alpha} \Delta \hat{R}_{l's'\beta} - \Delta \hat{W}_{n-n}^{\text{ref}}(\mathbf{R}). \quad ($$

# Diagrammatic representation



# Lowest-order electronic self-energy

$$\text{---} \rightarrow = \text{---} \rightarrow + \text{---} \rightarrow \Sigma \text{---} \rightarrow$$

(a)

$$\Sigma = \Sigma_k^H + \Sigma_k^{DW} + \boxed{\Sigma_k^{n-n} + \Sigma_k^{TF_{e-p}}}$$

In general, non-zero !  
They cancel each other  
when the equilibrium geometry  
is coherent with the level  
of approximation

# Next-order electronic self-energy

Result :

- after suppression of the tad-pole and 1st order phonon (suppose correct geometry)
- at the GW level

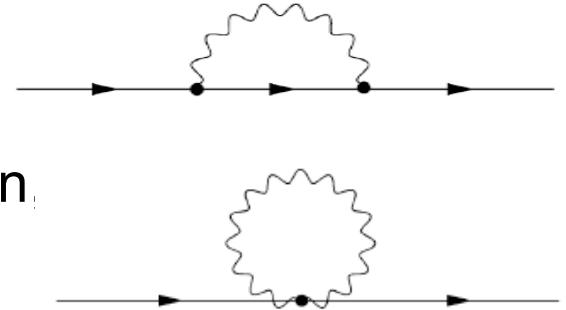


FIG. 10. The Dyson equation at the *GW* level in the electron-electron and electron-phonon interaction. The electron-phonon diagram is known as Fan self-energy and its vertex (represented by the circled dot) represents a dressed electron-phonon interaction [see Eq. (76)]. The wiggled line is a dressed electron-electron interaction [see Eq. (77)]. The most important aspect of this diagram is that, as long as only skeleton diagrams are included, the second-order electron-phonon interaction, and consequently the DW diagram, is not screened.

Confirmation of the screening of the 1st order electron-phonon vertex`  
Of course, the screening « flavor » differs from the DFT one ...  
Screening of the DW diagram comes from self-consistency !

# Summary

- Integration over the phonon degrees of freedom yields thermodynamic quantities, thermal expansion, T-dependent electronic structure



- Many effects are to be taken into account : thermal expansion, Fan, Debye-Waller, dynamical self-energy, anharmonicities, non-rigid ion behaviour, delicate sampling of the phonon Brillouin zone, accurate starting electronic structure (GW), accurate electron-phonon coupling (GW) ...
- The static AHC (Fan + Debye-Waller) breaks down for infra-red active solids
- Still lot of work to do to improve our tools !
- Unified MBPT of electron, phonons and electron-phonon coupling

